TPS54240 3.5-V to 42-V Step-Down DC - DC Converter With Eco-Mode™

1 Features

- 3.5-V to 42-V Input Voltage Range
- 200-mΩ High-Side MOSFET
- High Efficiency at Light Loads With a Pulse Skipping Eco-Mode™
- 138-µA Operating Quiescent Current
- 1.3-µA Shutdown Current
- 100-kHz to 2.5-MHz Switching Frequency
- Synchronizes to External Clock
- Adjustable Slow Start and Sequencing
- UV and OV Power Good Output
- Adjustable UVLO Voltage and Hysteresis
- 0.8-V Internal Voltage Reference
- 10-Pin HVSSOP and 10-Pin 3-mm x 3-mm VSON Packages with PowerPAD™
- Supported by WEBENCH® Software Tool

2 Applications

- 12-V and 24-V Industrial and Commercial Low-Power Systems
- GSM, GPRS Modules in Fleet Management, eMeters, and Security Systems

3 Description

The TPS54240 device is a 42-V, 2.5-A, step-down regulator with an integrated high-side MOSFET. Current mode control provides simple external compensation and flexible component selection. A low-ripple, pulse skip mode reduces the no load, regulated output supply current to 138 µA. Using the enable pin, shutdown supply current is reduced to 1.3 µA, when the enable pin is low.

Undervoltage lockout is internally set at 2.5 V, but it can be increased using the enable pin. The output voltage startup ramp is controlled by the slow-start pin that can also be configured for sequencing and tracking. An open-drain power good signal indicates the output is within 94% to 107% of its nominal voltage.

A wide switching frequency range allows efficiency and optimization of external component size. Frequency foldback and thermal shutdown protects the part during an overload condition.

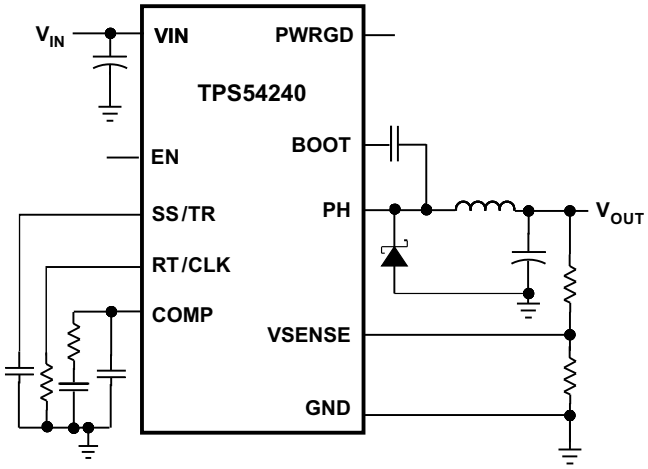
The TPS54240 is available in 10-pin, thermally-enhanced HVSSOP and 10-pin 3-mm x 3-mm PowerPAD package.

Device Information(1)

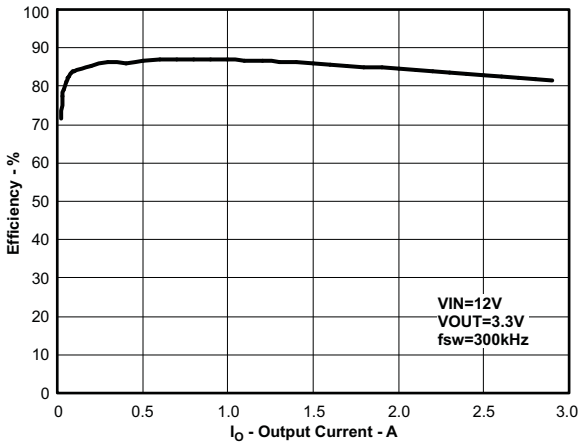
PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS54240	HVSSOP (10)	3.00 mm x 3.00 mm
	VSON (10)	

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic



Efficiency vs Load Current



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers of current version may differ from previous versions.

Changes from Revision A (April 2010) to Revision B — **Page**

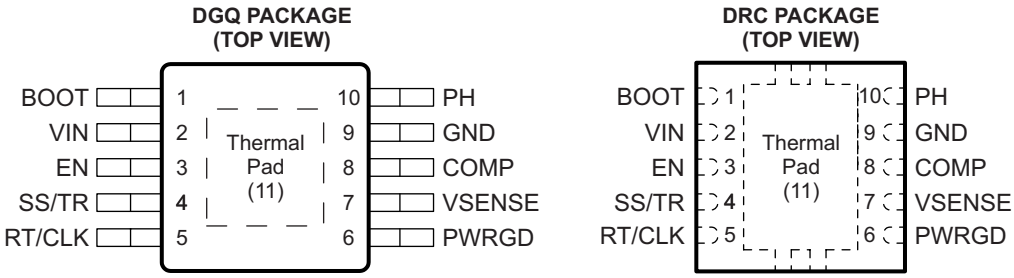
- Added *Pin Configuration and Functions* section, *Handling Rating* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section ... 1
- Changed the Start Input Voltage value in Design Requirements from 6.0 V to 6.25 V ... 31
- Changed the Stop Input Voltage value in Design Requirements from 5.5 V to 5.9 V ... 31
- Changed the value 6.0 V to 6.25 V ... 36
- Changed the value 5.5 V to 5.9 V ... 36
- Changed the value 6.0 V to 6.25 V ... 36
- Changed the value 5.5 V to 5.9 V ... 36

Changes from Original (April 2010) to Revision A — **Page**

- Added 10-Pin 3mm x 3mm SON to Features ... 1
- Added Thermal Information table and deleted Package Dissipation Ratings table ... 4

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5 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
BOOT	1	O	A bootstrap capacitor is required between BOOT and PH. If the voltage on this capacitor is below the minimum required by the output device, the output is forced to switch off until the capacitor is refreshed.
COMP	8	O	Error amplifier output, and input to the output switch current comparator. Connect frequency compensation components to this pin.
EN	3	I	Enable pin, internal pullup current source. Pull below 1.2 V to disable. Float to enable. Adjust the input undervoltage lockout with two resistors.
GND	9	–	Ground
PH	10	I	The source of the internal high-side power MOSFET.
POWERPAD	11	–	GND pin must be electrically connected to the exposed pad on the printed circuit board for proper operation.
PWRGD	6	O	An open-drain output, asserts low if output voltage is low due to thermal shutdown, dropout, overvoltage or EN shut down.
RT/CLK	5	I	Resistor Timing and External Clock. An internal amplifier holds this pin at a fixed voltage when using an external resistor to ground to set the switching frequency. If the pin is pulled above the PLL upper threshold, a mode change occurs and the pin becomes a synchronization input. The internal amplifier is disabled and the pin is a high impedance clock input to the internal PLL. If clocking edges stop, the internal amplifier is re-enabled and the mode returns to a resistor set function.
SS/TR	4	I	Slow-Start and Tracking. An external capacitor connected to this pin sets the output rise time. Since the voltage on this pin overrides the internal reference, it can be used for tracking and sequencing.
VIN	2	I	Input supply voltage, 3.5 V to 42 V.
VSENSE	7	I	Inverting node of the transconductance (gm) error amplifier.

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6 Specifications

6.1 Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Input voltage	VIN	–0.3	47	V
	EN	–0.3	5	
	VSENSE	–0.3	3	
	COMP	–0.3	3	
	PWRGD	–0.3	6	
	SS/TR	–0.3	3	
	RT/CLK	–0.3	3.6	
Output voltage	BOOT-PH		8	V
	PH	–0.6	47	
	PH, 10-ns Transient	–2	47	
Voltage difference	PAD to GND		±200	mV
Source current	EN		100	µA
	BOOT		100	mA
	VSENSE		10	µA
	PH	Current Limit		A
	RT/CLK		100	µA
Sink current	VIN	Current Limit		A
	COMP		100	µA
	PWRGD		10	mA
	SS/TR		200	µA
Operating junction temperature		–40	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Handling Ratings

			MIN	MAX	UNIT
T_{stg}	Storage temperature range		–65	150	°C
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	-2	2	kV
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins(2)	-500	500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Operating Input Voltage on (VIN pin)	3.5	42	V
Operating junction temperature, T_J	-40	150	°C

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6.4 Thermal Information

THERMAL METRIC (1) (2) (2)		TPS54240		UNIT
		DGQ	DRC	
		10 PINS	10 PINS	
θ_{JA}	Junction-to-ambient thermal resistance (standard board)	62.5	40	°C/W
ψ_{JT}	Junction-to-top characterization parameter	1.7	0.6	
ψ_{JB}	Junction-to-board characterization parameter	20.1	7.5	
θ_{JCtop}	Junction-to-case(top) thermal resistance	83	65	
θ_{JCbot}	Junction-to-case(bottom) thermal resistance	21	7.8	
θ_{JB}	Junction-to-board thermal resistance	28	8	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
(2) Power rating at a specific ambient temperature TA should be determined with a junction temperature of 150°C. This is the point where distortion starts to substantially increase. See power dissipation estimate in application section of this data sheet for more information.

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6.5 Electrical Characteristics

T_J = –40°C to 150°C, VIN = 3.5 to 42 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY VOLTAGE (VIN PIN)					
Operating input voltage		3.5		42	V
Internal undervoltage lockout threshold	No voltage hysteresis, rising and falling		2.5		V
Shutdown supply current	EN = 0 V, 25°C, 3.5 V ≤ VIN ≤ 42 V		1.3	4	µA
Operating : nonswitching supply current	VSENSE = 0.83 V, VIN = 12 V, 25°C		138	200	µA
ENABLE AND UVLO (EN PIN)					
Enable threshold voltage	No voltage hysteresis, rising and falling, 25°C	1.15	1.25	1.36	V
Input current	Enable threshold +50 mV		–3.8		µA
	Enable threshold –50 mV		–0.9		µA
Hysteresis current			–2.9		µA
VOLTAGE REFERENCE					
Voltage reference	T_J = 25°C	0.792	0.8	0.808	V
		0.784	0.8	0.816	V
HIGH-SIDE MOSFET					
On-resistance	VIN = 3.5 V, BOOT-PH = 3 V		300		mΩ
	VIN = 12 V, BOOT-PH = 6 V		200	410	mΩ
ERROR AMPLIFIER (EA)					
Input current			50		nA
Error amplifier transconductance (g_M)	–2 µA < I_{COMP} < 2 µA, V_{COMP} = 1 V		310		µS
Error amplifier transconductance (g_M) during slow start	–2 µA < I_{COMP} < 2 µA, V_{COMP} = 1 V, V_{VSENSE} = 0.4 V		70		µS
Error amplifier dc gain	V_{VSENSE} = 0.8 V		10,000		V/V
Error amplifier bandwidth			2700		kHz
Error amplifier source/sink	$V_{(COMP)}$ = 1 V, 100 mV overdrive		±27		µA
COMP to switch current transconductance			10.5		A/V

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Electrical Characteristics (continued)

T_J = –40°C to 150°C, VIN = 3.5 to 42 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CURRENT LIMIT						
	Current limit threshold	VIN = 12 V, T_J = 25°C	3.5	6.1		A
THERMAL SHUTDOWN						
	Thermal shutdown			182		°C
TIMING RESISTOR AND EXTERNAL CLOCK (RT/CLK PIN)						
	Switching Frequency Range using RT mode		100		2500	kHz
f_{SW}	Switching frequency	R_T = 200 kΩ	450	581	720	kHz
	Switching Frequency Range using CLK mode		300		2200	kHz
	Minimum CLK input pulse width			40		ns
	RT/CLK high threshold			1.9	2.2	V
	RT/CLK low threshold		0.5	0.7		V
	RT/CLK falling edge to PH rising edge delay	Measured at 500 kHz with RT resistor in series		60		ns
	PLL lock in time	Measured at 500 kHz		100		µs
SLOW-START AND TRACKING (SS/TR)						
	Charge current	$V_{SS/TR}$ = 0.4 V		2		µA
	SS/TR-to-VSENSE matching	$V_{SS/TR}$ = 0.4 V		45		mV
	SS/TR-to-reference crossover	98% nominal		1.15		V
	SS/TR discharge current (overload)	VSENSE = 0 V, V(SS/TR) = 0.4 V		382		µA
	SS/TR discharge voltage	VSENSE = 0 V		54		mV
POWERGOOD (PWRGD PIN)						
V_{VSENSE}	VSENSE threshold	VSENSE falling		92%		
		VSENSE rising		94%		
		VSENSE rising		109%		
		VSENSE falling		107%		
	Hysteresis	VSENSE falling		2%		
	Output high leakage	VSENSE = VREF, V(PWRGD) = 5.5 V, 25°C		10		nA
	On resistance	I(PWRGD) = 3 mA, VSENSE < 0.79 V		50		Ω
	Minimum VIN for defined output	V(PWRGD) < 0.5 V, I(PWRGD) = 100 µA		0.95	1.5	V

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6.6 Typical Characteristics

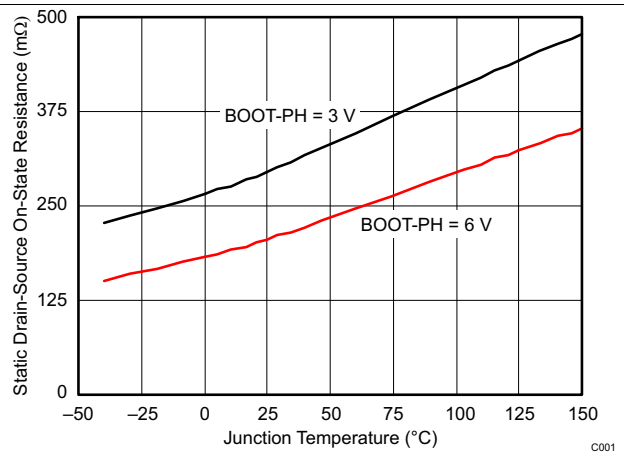


Figure 1. On Resistance vs Junction Temperature

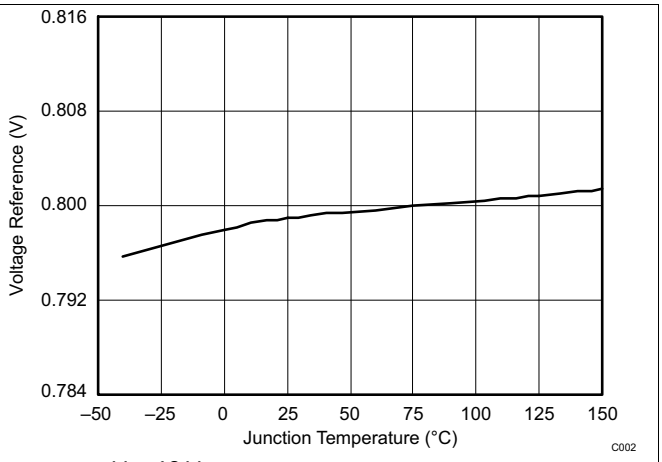


Figure 2. Voltage Reference vs Junction Temperature

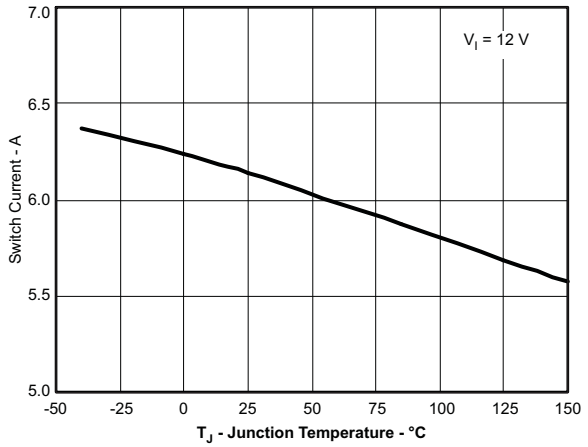


Figure 3. Switch Current Limit vs Junction Temperature

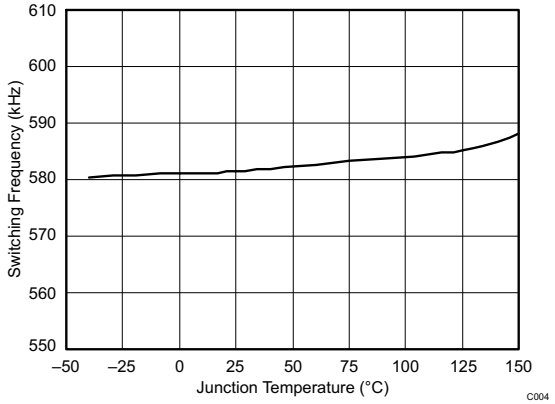


Figure 4. Switching Frequency vs Junction Temperature

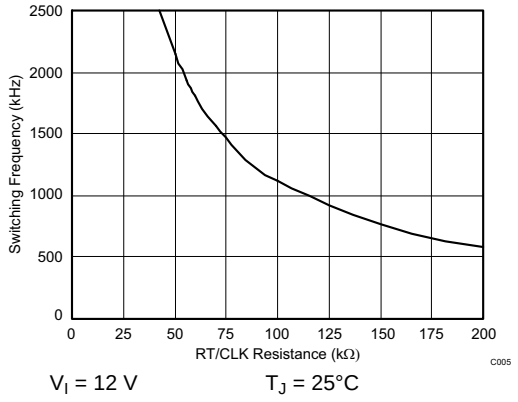


Figure 5. Switching Frequency vs RT/CLK Resistance High Frequency Range

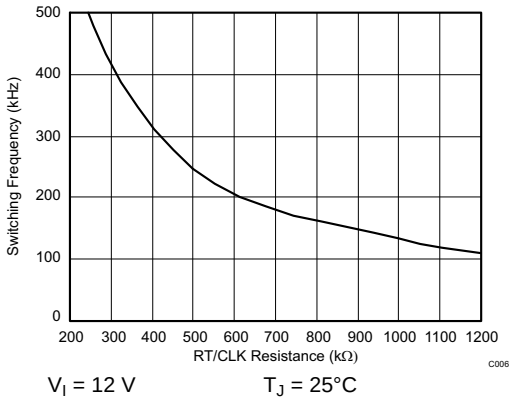


Figure 6. Switching Frequency vs RT/CLK Resistance Low Frequency Range

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Typical Characteristics (continued)

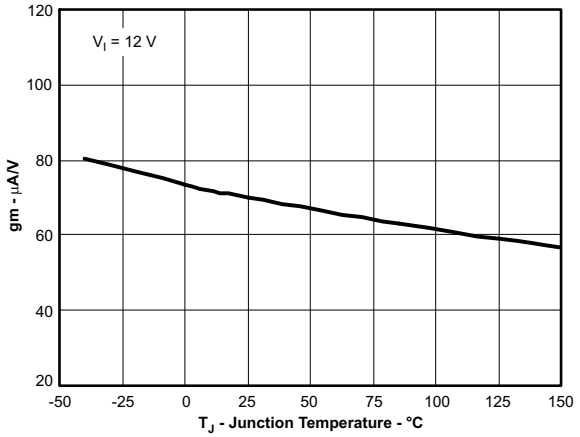


Figure 7. EA Transconductance during Slow Start vs Junction Temperature

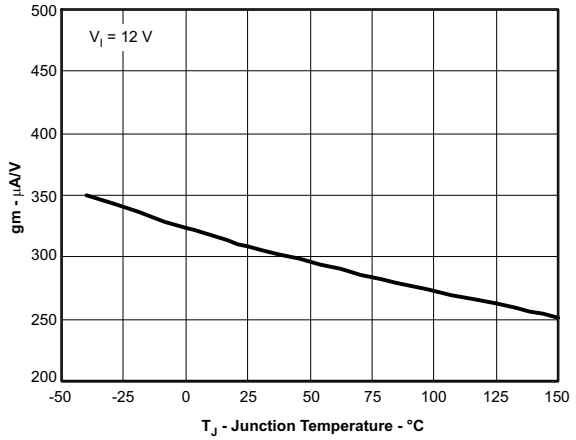


Figure 8. EA Transconductance vs Junction Temperature

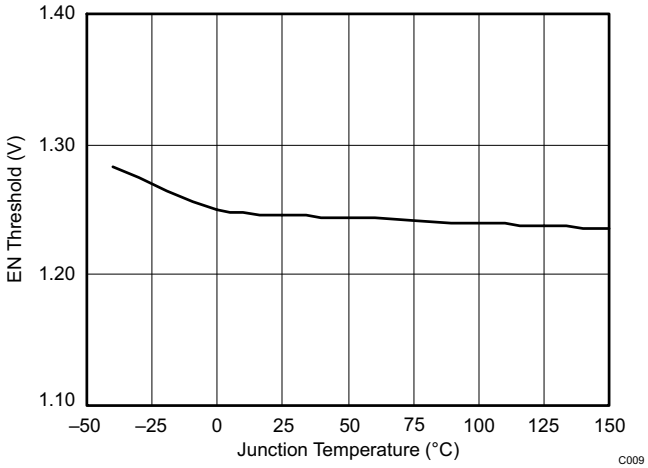


Figure 9. EN Pin Voltage vs Junction Temperature

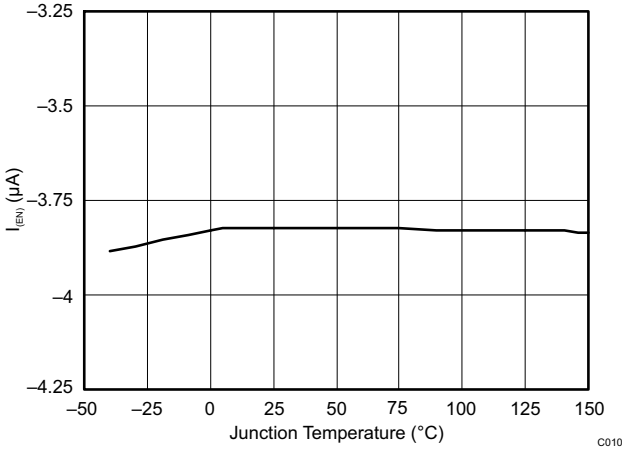


Figure 10. EN Pin Current vs Junction Temperature

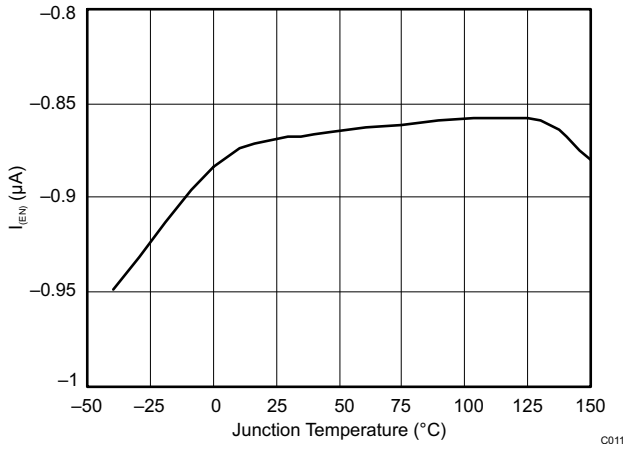


Figure 11. EN Pin Current vs Junction Temperature

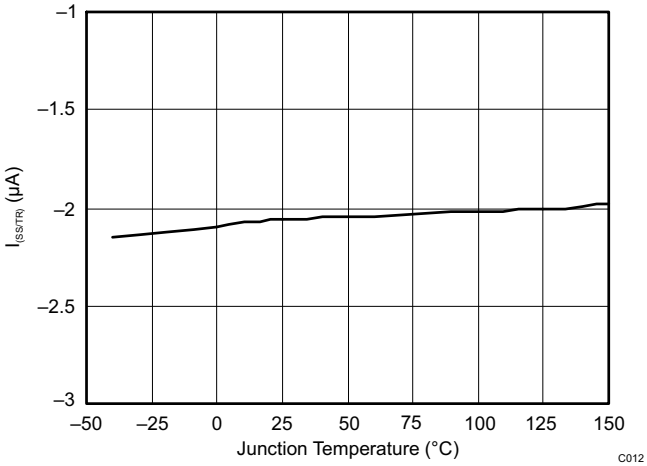


Figure 12. SS/TR Charge Current vs Junction Temperature

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Typical Characteristics (continued)

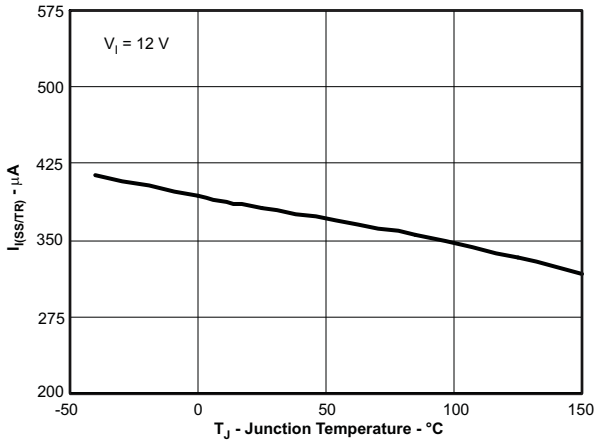


Figure 13. SS/TR Discharge Current vs Junction Temperature

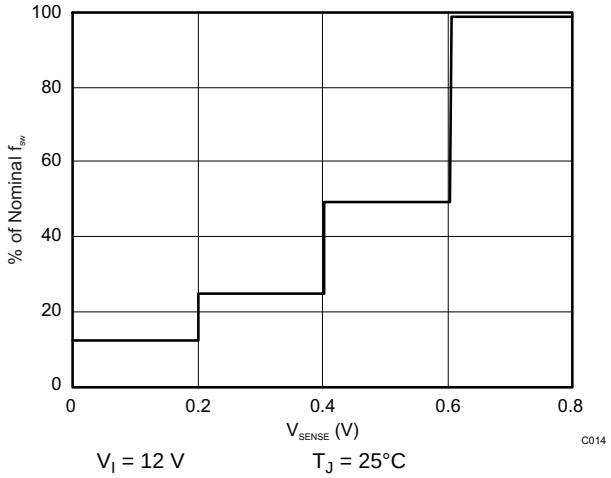


Figure 14. Switching Frequency vs VSENSE

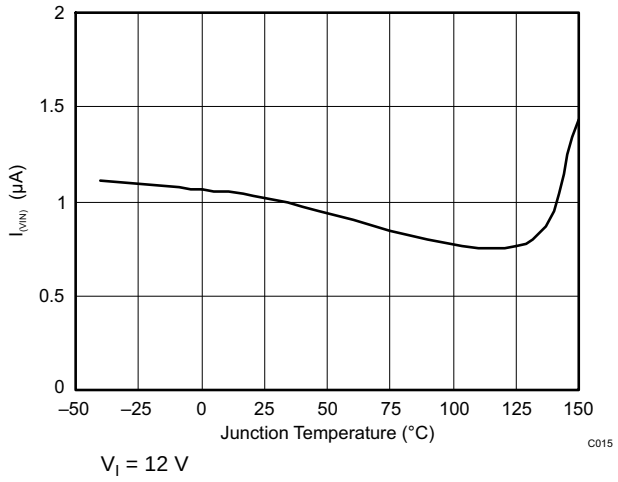


Figure 15. Shutdown Supply Current vs Junction Temperature

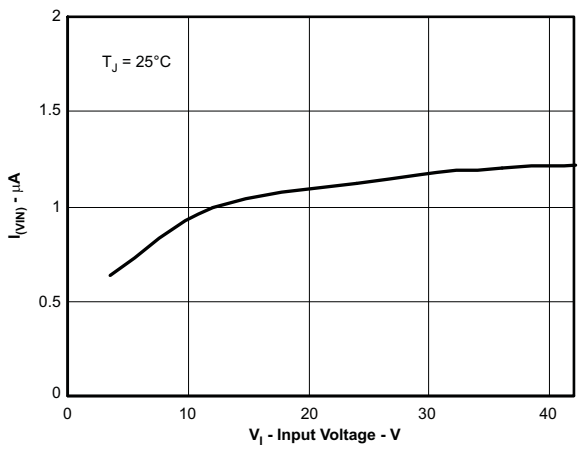


Figure 16. Shutdown Supply Current vs Input Voltage (VIN)

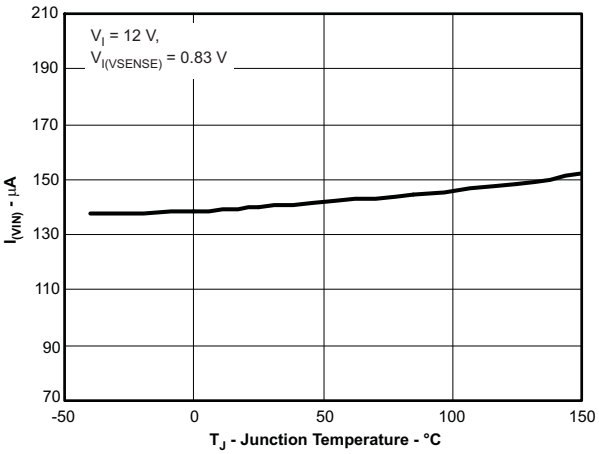


Figure 17. VIN Supply Current vs Junction Temperature

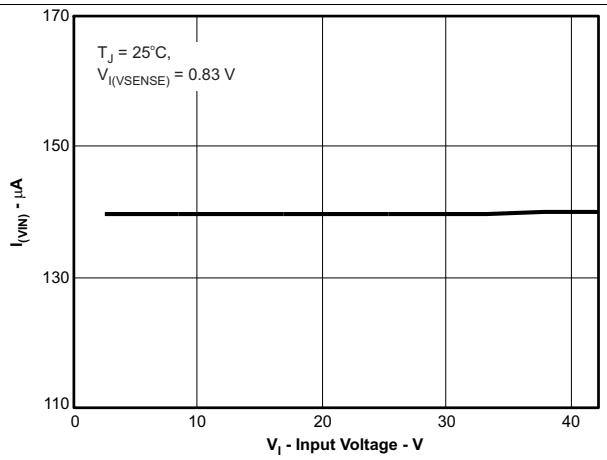


Figure 18. VIN Supply Current vs Input Voltage

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Typical Characteristics (continued)

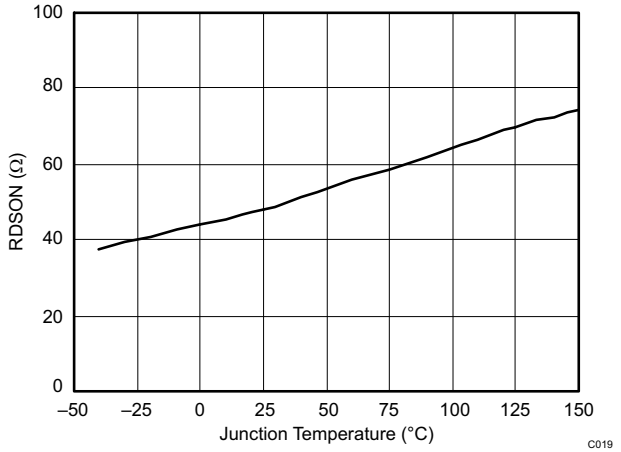


Figure 19. PWRGD on Resistance vs Junction Temperature

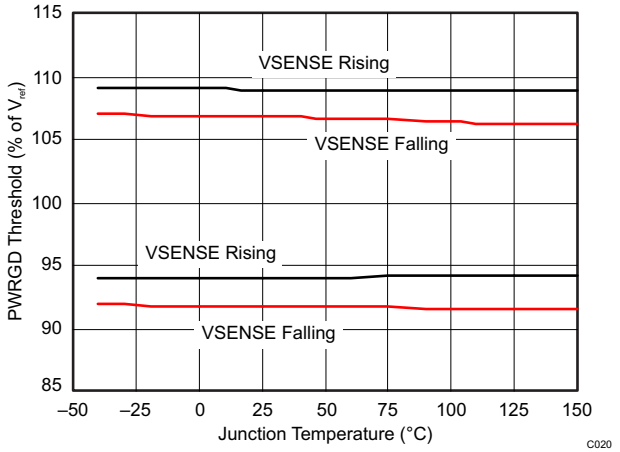


Figure 20. PWRGD Threshold vs Junction Temperature

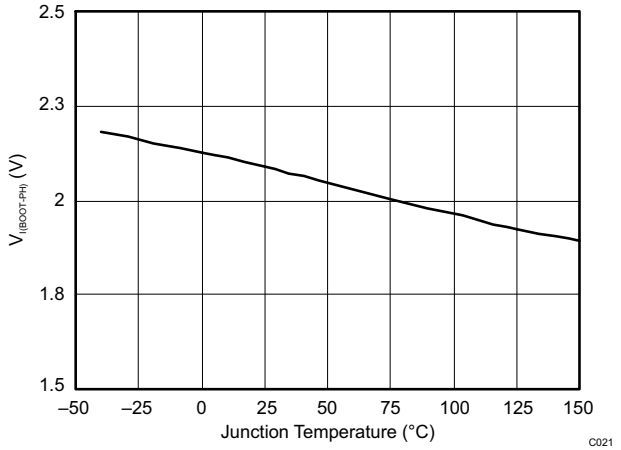


Figure 21. BOOT-PH UVLO vs Junction Temperature

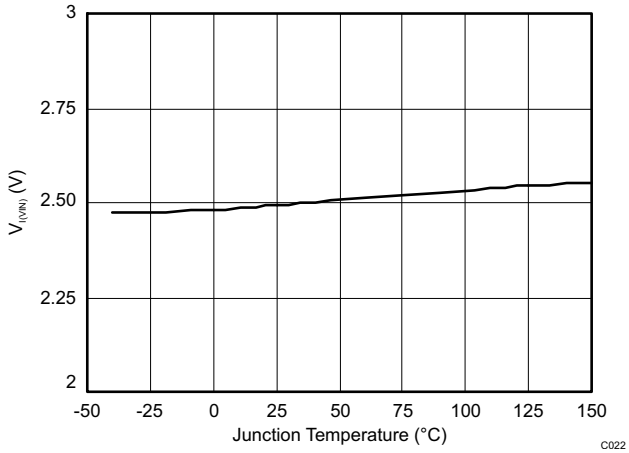


Figure 22. Input Voltage UVLO vs Junction Temperature

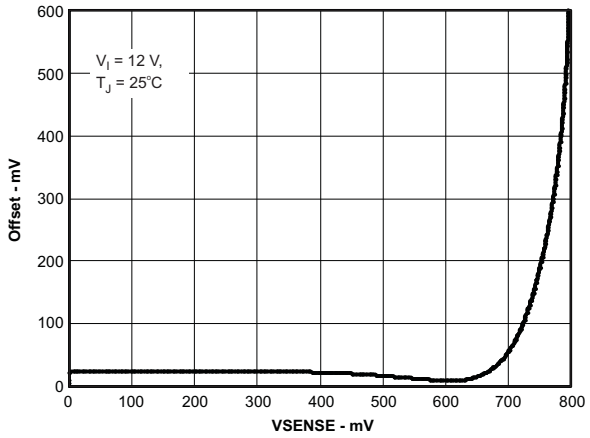


Figure 23. SS/TR to VSENSE Offset vs Vsense

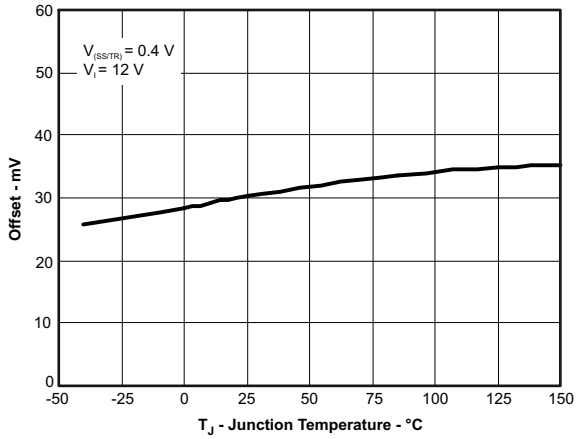


Figure 24. SS/TR to VSENSE Offset vs Temperature

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7 Detailed Description

7.1 Overview

The TPS54240 device is a 42-V, 2.5-A, step-down (buck) regulator with an integrated high-side n-channel MOSFET. To improve performance during line and load transients, the device implements a constant-frequency, current mode control which reduces output capacitance and simplifies external frequency compensation design. The wide-switching frequency of 100 kHz to 2500 kHz allows for efficiency and size optimization when selecting the output filter components. The switching frequency is adjusted using a resistor to ground on the RT/CLK pin. The device has an internal phase-lock loop (PLL) on the RT/CLK pin that is used to synchronize the power switch turn on to a falling edge of an external system clock.

The TPS54240 has a default startup voltage of approximately 2.5 V. The EN pin has an internal pullup current source that can be used to adjust the input voltage undervoltage lockout (UVLO) threshold with two external resistors. In addition, the pullup current provides a default condition. When the EN pin is floating, the device will operate. The operating current is 138 µA when not switching and under no load. When the device is disabled, the supply current is 1.3 µA.

The integrated 200-mΩ high-side MOSFET allows for high-efficiency power supply designs capable of delivering 2.5 amperes of continuous current to a load. The TPS54240 reduces the external component count by integrating the boot recharge diode. The bias voltage for the integrated high-side MOSFET is supplied by a capacitor on the BOOT to PH pin. The boot capacitor voltage is monitored by an UVLO circuit and will turn the high-side MOSFET off when the boot voltage falls below a preset threshold. The TPS54240 can operate at high duty cycles because of the boot UVLO. The output voltage can be stepped down to as low as the 0.8-V reference.

The TPS54240 has a power good comparator (PWRGD) which asserts when the regulated output voltage is less than 92% or greater than 109% of the nominal output voltage. The PWRGD pin is an open drain output which deasserts when the VSENSE pin voltage is between 94% and 107% of the nominal output voltage allowing the pin to transition high when a pullup resistor is used.

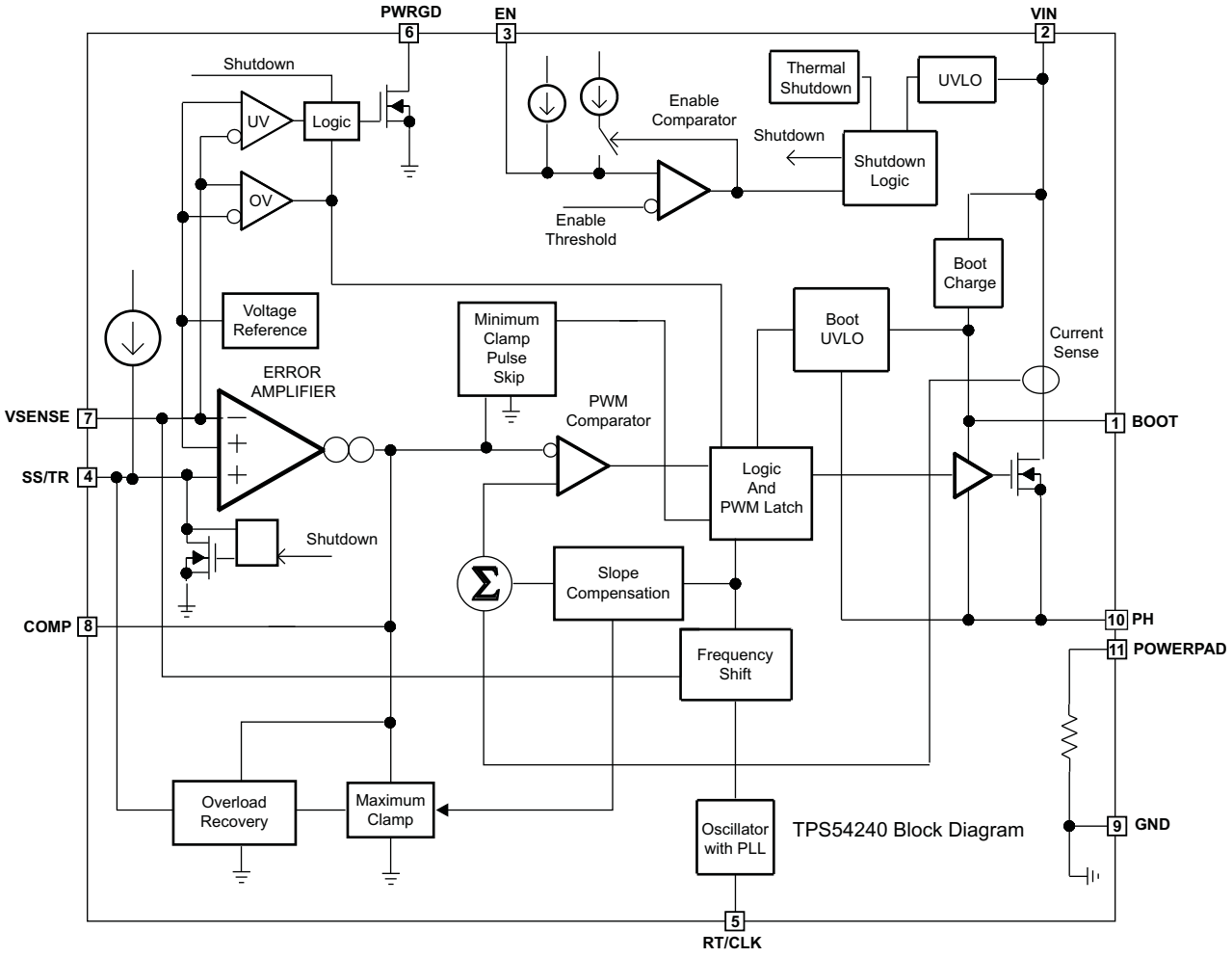
The TPS54240 minimizes excessive output overvoltage (OV) transients by taking advantage of the OV powergood comparator. When the OV comparator is activated, the high-side MOSFET is turned off and masked from turning on until the output voltage is lower than 107%.

The SS/TR (slow-start / tracking) pin is used to minimize inrush currents or provide power supply sequencing during power-up. A small value capacitor should be coupled to the pin to adjust the slow-start time. A resistor divider can be coupled to the pin for critical power supply sequencing requirements. The SS/TR pin is discharged before the output powers up. This discharging ensures a repeatable restart after an over-temperature fault, UVLO fault or a disabled condition.

The TPS54240, also, discharges the slow-start capacitor during overload conditions with an overload recovery circuit. The overload recovery circuit will slow start the output from the fault voltage to the nominal regulation voltage once a fault condition is removed. A frequency foldback circuit reduces the switching frequency during startup and overcurrent fault conditions to help control the inductor current.

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7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Fixed Frequency PWM Control

The TPS54240 uses an adjustable fixed frequency, peak current mode control. The output voltage is compared through external resistors on the VSENSE pin to an internal voltage reference by an error amplifier which drives the COMP pin. An internal oscillator initiates the turn on of the high-side power switch. The error amplifier output is compared to the high-side power switch current. When the power switch current reaches the level set by the COMP voltage, the power switch is turned off. The COMP pin voltage will increase and decrease as the output current increases and decreases. The device implements a current limit by clamping the COMP pin voltage to a maximum level. The Eco-Mode is implemented with a minimum clamp on the COMP pin.

7.3.2 Slope Compensation Output Current

The TPS54240 adds a compensating ramp to the switch current signal. This slope compensation prevents sub-harmonic oscillations. The available peak inductor current remains constant over the full duty cycle range.

7.3.3 Pulse Skip Eco-Mode

The TPS54240 operates in a pulse skip Eco-Mode at light load currents to improve efficiency by reducing switching and gate drive losses. The TPS54240 is designed so that if the output voltage is within regulation and the peak switch current at the end of any switching cycle is below the pulse-skipping current threshold, the device enters Eco-Mode. This current threshold is the current level corresponding to a nominal COMP voltage or 500 mV.

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Feature Description (continued)

When in Eco-Mode, the COMP pin voltage is clamped at 500 mV and the high-side MOSFET is inhibited. Further decreases in load current or in output voltage cannot drive the COMP pin below this clamp voltage level.

Since the device is not switching, the output voltage begins to decay. As the voltage control loop compensates for the falling output voltage, the COMP pin voltage begins to rise. At this time, the high-side MOSFET is enabled and a switching pulse initiates on the next switching cycle. The peak current is set by the COMP pin voltage. The output voltage re-charges the regulated value, then the peak switch current starts to decrease, and eventually falls below the Eco-Mode threshold at which time the device again enters Eco-Mode.

For Eco-Mode operation, the TPS54240 senses peak current, not average or load current, so the load current where the device enters Eco-Mode is dependent on the output inductor value. For example, the circuit in Figure 49 enters Eco-Mode at about 5 mA of output current. When the load current is low and the output voltage is within regulation, the device enters a sleep mode and draws only 138-µA input quiescent current. The internal PLL remains operating when in sleep mode. When operating at light load currents in the pulse skip mode, the switching transitions occur synchronously with the external clock signal.

7.3.4 Low Dropout Operation and Bootstrap Voltage (BOOT)

The TPS54240 has an integrated boot regulator, and requires a small ceramic capacitor between the BOOT and PH pins to provide the gate drive voltage for the high-side MOSFET. The BOOT capacitor is refreshed when the high-side MOSFET is off and the low-side diode conducts. The value of this ceramic capacitor should be 0.1 µF. A ceramic capacitor with an X7R or X5R grade dielectric with a voltage rating of 10 V or higher is recommended because of the stable characteristics overtemperature and voltage.

To improve drop out, the TPS54240 is designed to operate at 100% duty cycle as long as the BOOT to PH pin voltage is greater than 2.1 V. When the voltage from BOOT to PH drops below 2.1 V, the high-side MOSFET is turned off using an UVLO circuit which allows the low-side diode to conduct and refresh the charge on the BOOT capacitor. Since the supply current sourced from the BOOT capacitor is low, the high-side MOSFET can remain on for more switching cycles than are required to refresh the capacitor, thus the effective duty cycle of the switching regulator is high.

The effective duty cycle during dropout of the regulator is mainly influenced by the voltage drops across the power MOSFET, inductor resistance, low-side diode and printed circuit board resistance. During operating conditions in which the input voltage drops and the regulator is operating in continuous conduction mode, the high-side MOSFET can remain on for 100% of the duty cycle to maintain output regulation, until the BOOT to PH voltage falls below 2.1 V.

Take care of maximum duty cycle applications which experience extended time periods with light loads or no load. When the voltage across the BOOT capacitor falls below the 2.1-V UVLO threshold, the high-side MOSFET is turned off, but there may not be enough inductor current to pull the PH pin down to recharge the BOOT capacitor. The high-side MOSFET of the regulator stops switching because the voltage across the BOOT capacitor is less than 2.1 V. The output capacitor then decays until the difference in the input voltage and output voltage is greater than 2.1 V, at which point the BOOT UVLO threshold is exceeded, and the device starts switching again until the desired output voltage is reached. This operating condition persists until the input voltage and/or the load current increases. It is recommended to adjust the VIN stop voltage greater than the BOOT UVLO trigger condition at the minimum load of the application using the adjustable VIN UVLO feature with resistors on the EN pin.

The start and stop voltages for typical 3.3-V and 5-V output applications are shown in Figure 25 and Figure 26. The voltages are plotted versus load current. The start voltage is defined as the input voltage needed to regulate the output within 1%. The stop voltage is defined as the input voltage at which the output drops by 5% or stops switching.

During high-duty cycle conditions, the inductor current ripple increases while the BOOT capacitor is being recharged resulting in an increase in ripple voltage on the output. This is due to the recharge time of the boot capacitor being longer than the typical high-side off-time when switching occurs every cycle.

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Feature Description (continued)

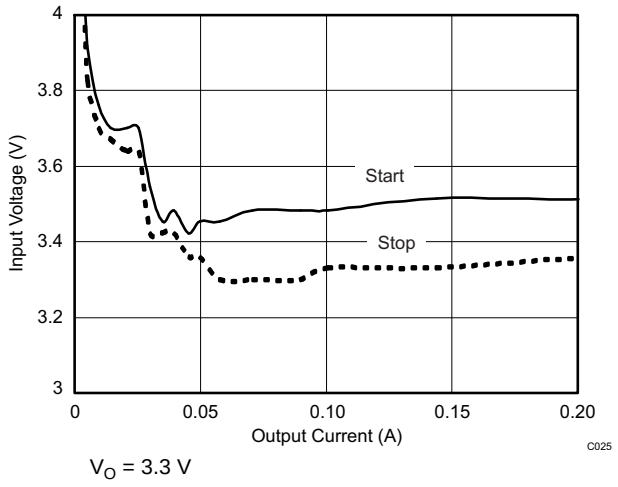


Figure 25. 3.3 V Start / Stop Voltage

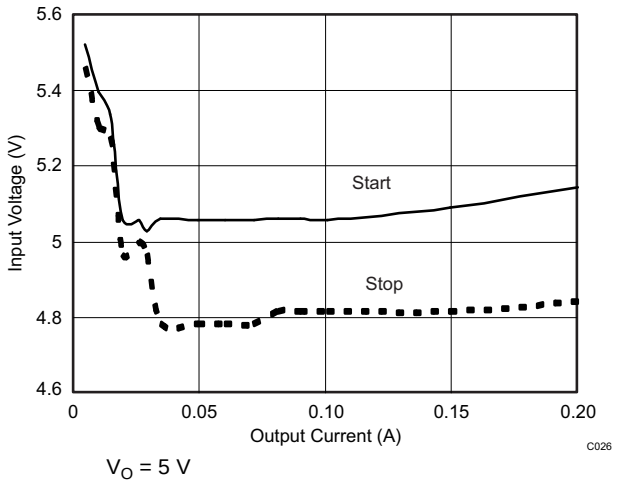


Figure 26. 5.0 V Start / Stop Voltage

7.3.5 Error Amplifier

The TPS54240 has a transconductance amplifier for the error amplifier. The error amplifier compares the VSENSE voltage to the lower of the SS/TR pin voltage or the internal 0.8-V voltage reference. The transconductance (g_M) of the error amplifier is 310 µA/V during normal operation. During the slow-start operation, the transconductance is a fraction of the normal operating gm. When the voltage of the VSENSE pin is below 0.8 V and the device is regulating using the SS/TR voltage, the gm is 70 µA/V.

The frequency compensation components (capacitor, series resistor and capacitor) are added to the COMP pin to ground.

7.3.6 Voltage Reference

The voltage reference system produces a precise ±2% voltage reference over temperature by scaling the output of a temperature stable bandgap circuit.

7.3.7 Adjusting The Output Voltage

The output voltage is set with a resistor divider from the output node to the VSENSE pin. TI recommends using 1% tolerance or better divider resistors. Start with a 10-kΩ for the R2 resistor and use the Equation 1 to calculate R1. To improve efficiency at light loads, consider using larger value resistors. If the values are too high, the regulator will be more susceptible to noise and voltage errors from the VSENSE input current will be noticeable.

$$R1 = R2 \times \left(\frac{Vout - 0.8V}{0.8\ V} \right) \quad (1)$$

7.3.8 Enable And Adjusting Undervoltage Lockout

The TPS54240 is disabled when the VIN pin voltage falls below 2.5 V. If an application requires a higher undervoltage lockout (UVLO), use the EN pin as shown in Figure 27 to adjust the input voltage UVLO by using the two external resistors. Though it is not necessary to use the UVLO adjust registers, for operation it is highly recommended to provide consistent power-up behavior. The EN pin has an internal pullup current source, I1, of 0.9 µA that provides the default condition of the TPS54240 operating when the EN pin floats. Once the EN pin voltage exceeds 1.25 V, an additional 2.9 µA of hysteresis, Ihys, is added. This additional current facilitates input voltage hysteresis. Use Equation 2 to set the external hysteresis for the input voltage. Use Equation 3 to set the input start voltage.

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Feature Description (continued)

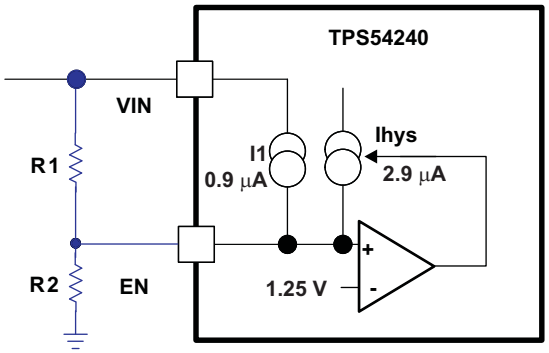


Figure 27. Adjustable Undervoltage Lockout (UVLO)

$$R1 = \frac{V_{START} - V_{STOP}}{I_{HYS}} \quad (2)$$

$$R2 = \frac{V_{ENA}}{\frac{V_{START} - V_{ENA}}{R1} + I_1} \quad (3)$$

Another technique to add input voltage hysteresis is shown in Figure 28. This method may be used, if the resistance values are high from the previous method and a wider voltage hysteresis is needed. The resistor R3 sources additional hysteresis current into the EN pin.

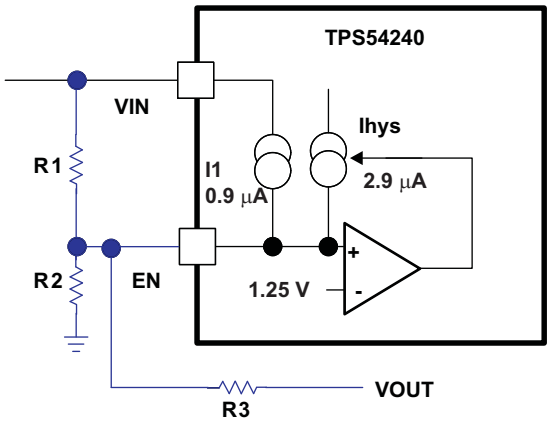


Figure 28. Adding Additional Hysteresis

$$R1 = \frac{V_{START} - V_{STOP}}{I_{HYS} + \frac{V_{OUT}}{R3}} \quad (4)$$

$$R2 = \frac{V_{ENA}}{\frac{V_{START} - V_{ENA}}{R1} + I_1 - \frac{V_{ENA}}{R3}} \quad (5)$$

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Feature Description (continued)

7.3.9 Slow-Start / Tracking Pin (SS/TR)

The TPS54240 effectively uses the lower voltage of the internal voltage reference, or the SS/TR pin voltage as the power supply's reference voltage, and regulates the output accordingly. A capacitor on the SS/TR pin-to-ground implements a slow start time. The TPS54240 has an internal pullup current source of 2 µA that charges the external slow start capacitor. The calculations for the slow start time (10% to 90%) are shown in Equation 6. The voltage reference (V_{REF}) is 0.8 V and the slow start current (I_{SS}) is 2 µA. The slow-start capacitor should remain lower than 0.47 µF and greater than 0.47 nF.

$$Css(nF) = \frac{Tss(ms) \times Iss(\mu A)}{Vref\ (V) \times 0.8} \quad (6)$$

At power-up, the TPS54240 will not start switching until the slow-start pin is discharged to less than 40 mV. To ensure a proper power up, see Figure 29.

Also, during normal operation, the TPS54240 will stop switching and the SS/TR must be discharged to 40 mV. When the VIN UVLO is exceeded, the EN pin must be pulled below 1.25 V, or a thermal shutdown event occurs.

The VSENSE voltage will follow the SS/TR pin voltage with a 45-mV offset up to 85% of the internal voltage reference. When the SS/TR voltage is greater than 85% on the internal reference voltage the offset increases as the effective system reference transitions from the SS/TR voltage to the internal voltage reference (see Figure 23). The SS/TR voltage will ramp linearly until clamped at 1.7 V.

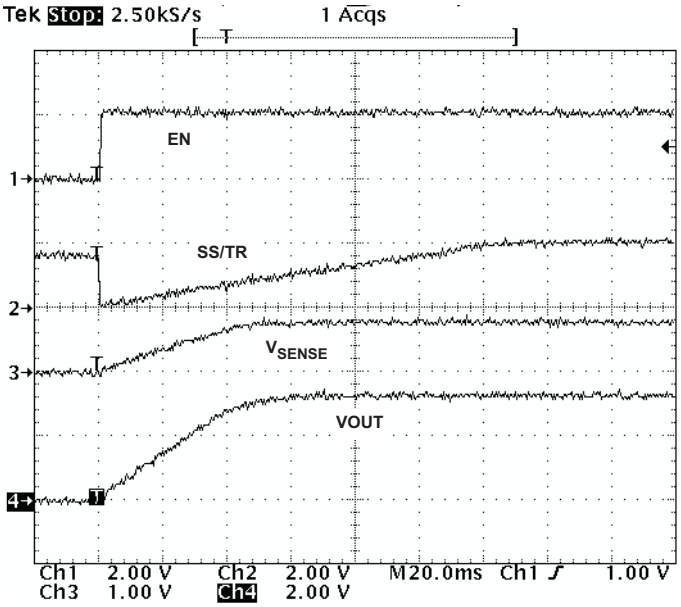


Figure 29. Operation of SS/TR Pin When Starting

7.3.10 Overload Recovery Circuit

The TPS54240 has an overload recovery (OLR) circuit. The OLR circuit will slow start the output from the overload voltage to the nominal regulation voltage once the fault condition is removed. The OLR circuit will discharge the SS/TR pin to a voltage slightly greater than the VSENSE pin voltage using an internal pulldown of 382 µA when the error amplifier is changed to a high voltage from a fault condition. When the fault condition is removed, the output will slow start from the fault voltage to nominal output voltage.

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Feature Description (continued)

7.3.11 Sequencing

Many of the common power supply sequencing methods can be implemented using the SS/TR, EN and PWRGD pins. The sequential method can be implemented using an open-drain output of a power on reset pin of another device. The sequential method is illustrated in Figure 30 using two TPS54240 devices. The powergood is coupled to the EN pin on the TPS54240, which will enable the second power supply once the primary supply reaches regulation. If needed, a 1-nF ceramic capacitor on the EN pin of the second power supply will provide a 1-ms startup delay. Figure 31 shows the results of Figure 30.

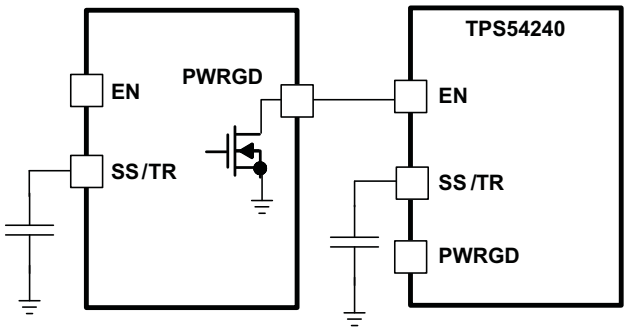


Figure 30. Schematic for Sequential Startup Sequence

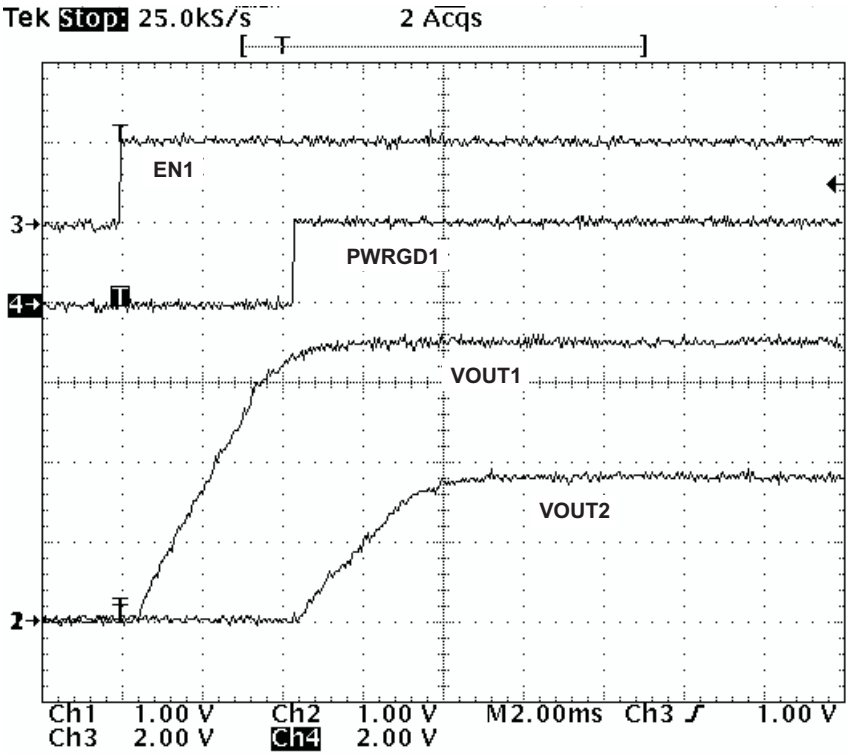


Figure 31. Sequential Startup Using EN and PWRGD

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Feature Description (continued)

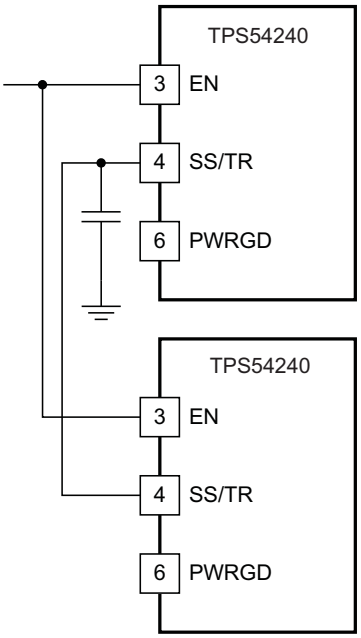


Figure 32. Schematic for Ratio-metric Startup Sequence

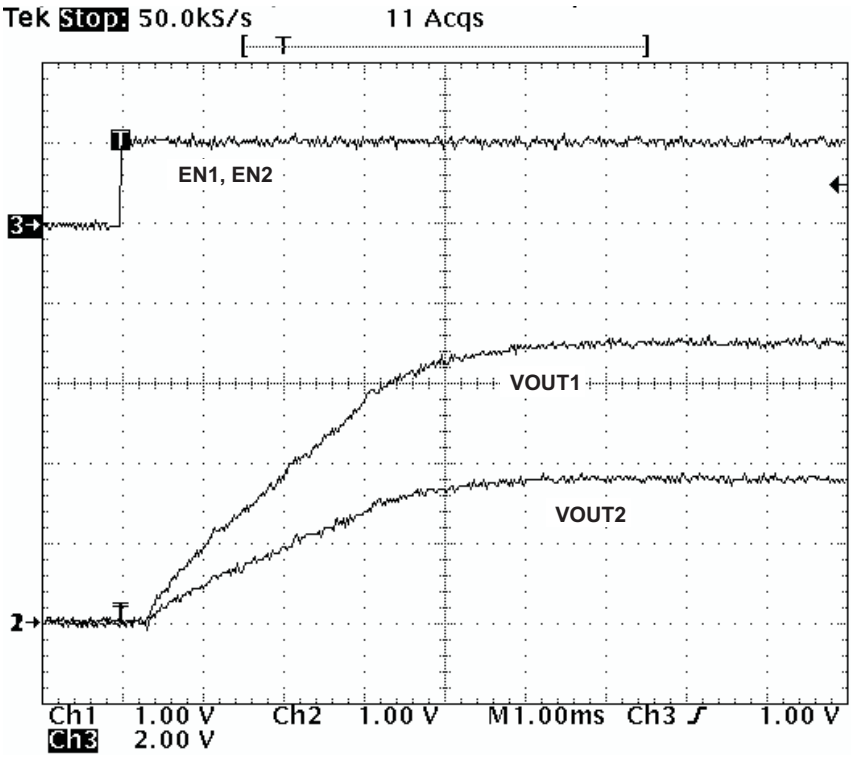


Figure 33. Ratio-metric Startup Using Coupled SS/TR Pins

Figure 32 shows a method for ratio-metric start up sequence by connecting the SS/TR pins together. The regulator outputs will ramp up and reach regulation at the same time. When calculating the slow-start time, the pullup current source must be doubled in Equation 6. Figure 33 shows the results of Figure 32.

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Feature Description (continued)

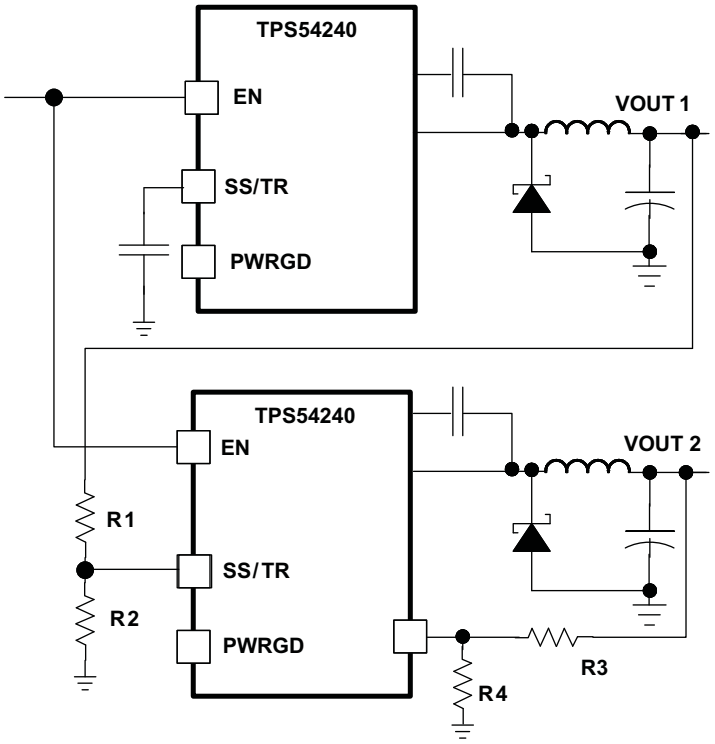


Figure 34. Schematic for Ratio-metric and Simultaneous Startup Sequence

Ratio-metric and simultaneous power supply sequencing can be implemented by connecting the resistor network of R1 and R2 shown in Figure 34 to the output of the power supply that needs to be tracked or another voltage reference source. Using Equation 7 and Equation 8, the tracking resistors can be calculated to initiate the Vout2 slightly before, after, or at the same time as Vout1. Equation 9 is the voltage difference between Vout1 and Vout2 at the 95% of nominal output regulation.

The deltaV variable is zero volts for simultaneous sequencing. To minimize the effect of the inherent SS/TR to VSENSE, offset (Vssoffset) in the slow-start circuit and the offset created by the pullup current source (ISS) and tracking resistors, the Vssoffset and Iss are included as variables in the equations.

To design a ratio-metric startup in which the Vout2 voltage is slightly greater than the Vout1 voltage when Vout2 reaches regulation, use a negative number in Equation 7 through Equation 9 for deltaV. Equation 9 will result in a positive number for applications which the Vout2 is slightly lower than Vout1 when Vout2 regulation is achieved.

Since the SS/TR pin must be pulled below 40 mV before starting after an EN, UVLO or thermal shutdown fault, careful selection of the tracking resistors is needed to ensure the device will restart after a fault. Make sure the calculated R1 value from Equation 7 is greater than the value calculated in Equation 10 to ensure the device can recover from a fault.

As the SS/TR voltage becomes more than 85% of the nominal reference voltage the Vssoffset becomes larger as the slow-start circuits gradually hands off the regulation reference to the internal voltage reference. The SS/TR pin voltage needs to be greater than 1.3 V for a complete handoff to the internal voltage reference as shown in Figure 23.

$$R1 = \frac{Vout2 + deltaV}{VREF} \times \frac{Vssoffset}{Iss} \quad (7)$$

$$R2 = \frac{VREF \times R1}{Vout2 + deltaV - VREF} \quad (8)$$

$$deltaV = Vout1 - Vout2 \quad (9)$$

$$R1 > 2800 \times Vout1 - 180 \times deltaV \quad (10)$$

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Feature Description (continued)

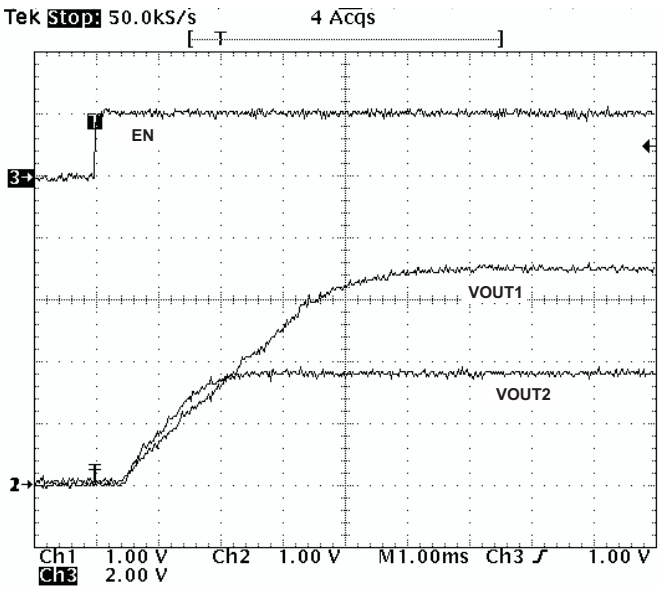


Figure 35. Ratio-metric Startup With Tracking Resistors

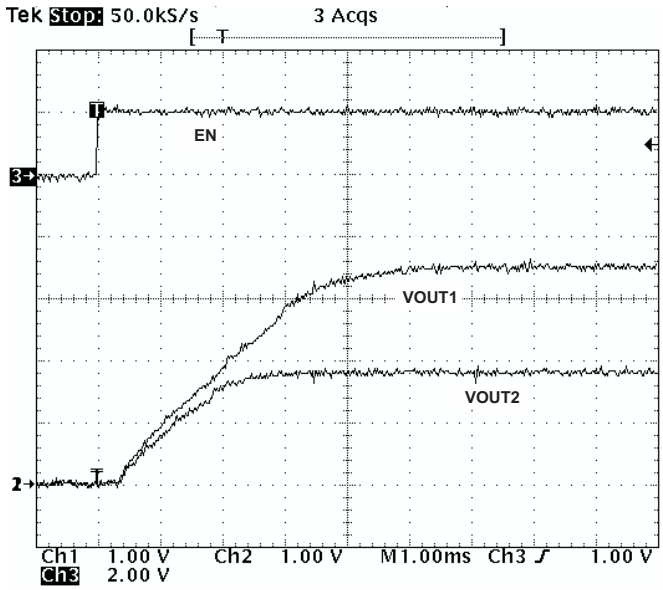


Figure 36. Ratio-metric Startup With Tracking Resistors

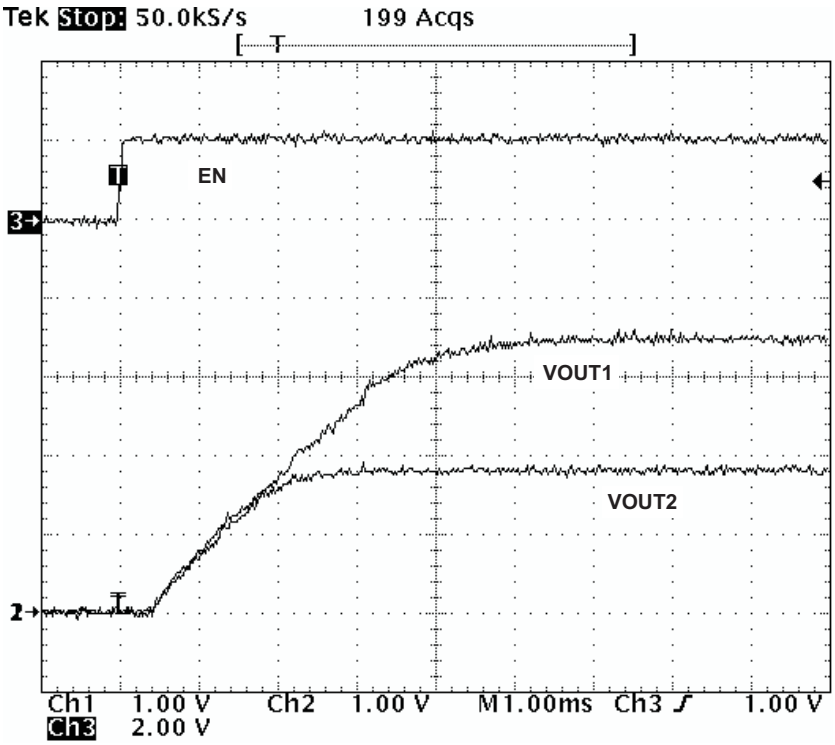


Figure 37. Simultaneous Startup With Tracking Resistor

Feature Description (continued)

7.3.12 Constant Switching Frequency and Timing Resistor (RT/CLK Pin)

The switching frequency of the TPS54240 is adjustable over a wide range from approximately 100 kHz to 2500 kHz by placing a resistor on the RT/CLK pin. The RT/CLK pin voltage is typically 0.5 V and must have a resistor-to-ground to set the switching frequency. To determine the timing resistance for a given switching frequency, use Equation 11 or the curves in Figure 38 or Figure 39. To reduce the solution size, one would typically set the switching frequency as high as possible, but tradeoffs of the supply efficiency, maximum input voltage and minimum controllable on time should be considered.

The minimum controllable on time is typically 135 ns and limits the maximum operating input voltage.

The maximum switching frequency is also limited by the frequency shift circuit. More discussion on the details of the maximum switching frequency is located below.

$$\text{RT (kOhm)} = \frac{206033}{f\text{sw (kHz)}^{1.0888}} \tag{11}$$

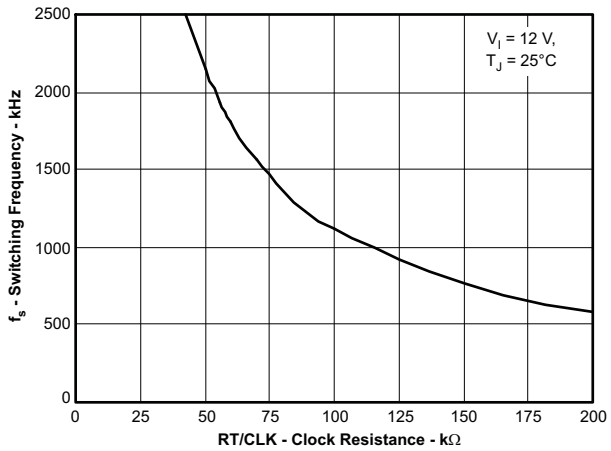


Figure 38. High Range RT

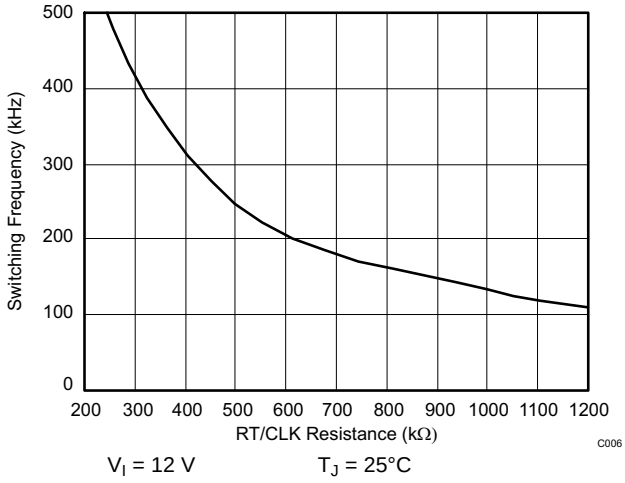


Figure 39. Low Range RT

7.3.13 Overcurrent Protection and Frequency Shift

The TPS54240 implements current mode control which uses the COMP pin voltage to turn off the high-side MOSFET on a cycle-by-cycle basis. Each cycle the switch current and COMP pin voltage are compared, when the peak switch current intersects the COMP voltage, the high-side switch is turned off. During overcurrent conditions that pull the output voltage low, the error amplifier will respond by driving the COMP pin high, increasing the switch current. The error amplifier output is clamped internally, which functions as a switch current limit.

To increase the maximum operating switching frequency at high-input voltages, the TPS54240 implements a frequency shift. The switching frequency is divided by 8, 4, 2, and 1 as the voltage ramps from 0 to 0.8 volts on VSENSE pin.

The device implements a digital frequency shift to enable synchronizing to an external clock during normal startup and fault conditions. Since the device can only divide the switching frequency by 8, there is a maximum input voltage limit in which the device operates and still have frequency shift protection.

During short-circuit events (particularly with high-input voltage applications), the control loop has a finite minimum controllable on time and the output has a low voltage. During the switch-on time, the inductor current ramps to the peak current limit because of the high-input voltage and minimum on time. During the switch-off time, the inductor would normally not have enough off-time and output voltage for the inductor to ramp down by the ramp-up amount. The frequency shift effectively increases the off-time allowing the current to ramp down.

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Feature Description (continued)

7.3.14 Selecting the Switching Frequency

The switching frequency that is selected should be the lower value of the two equations, Equation 12 and Equation 13. Equation 12 is the maximum switching frequency limitation set by the minimum controllable on-time. Setting the switching frequency above this value will cause the regulator to skip-switching pulses.

Equation 13 is the maximum switching frequency limit set by the frequency shift protection. To have adequate output short circuit protection at high-input voltages, the switching frequency should be set to be less than the $f_{SW(maxshift)}$ frequency. In Equation 13, to calculate the maximum switching frequency one must take into account that the output voltage decreases from the nominal voltage to 0 volts, the fdiv integer increases from 1 to 8, corresponding to the frequency shift.

In Figure 40, the solid line illustrates a typical safe operating area regarding frequency shift and assumes the output voltage is zero volts, and the resistance of the inductor is 0.130-Ω, MOSFET on resistance of 0.2 Ω and the diode voltage drop is 0.5 V. The dashed line is the maximum switching frequency to avoid pulse skipping. Enter these equations in a spreadsheet, or use the WEBENCH design software to determine the switching frequency.

$$f_{SW(max\,skip)} = \left(\frac{1}{t_{ON}}\right) \times \left(\frac{(I_L \times Rdc + V_{OUT} + Vd)}{(V_{IN} - I_L \times Rhs + Vd)}\right) \tag{12}$$

$$f_{SW(shift)} = \frac{fdiv}{t_{ON}} \times \left(\frac{(I_L \times Rdc + V_{OUTSC} + Vd)}{(V_{IN} - I_L \times Rhs + Vd)}\right) \tag{13}$$

I_L	inductor current
Rdc	inductor resistance
V_{IN}	maximum input voltage
V_{OUT}	output voltage
V_{OUTSC}	output voltage during short
Vd	diode voltage drop
$R_{DS(on)}$	switch on resistance
t_{ON}	controllable on time
f_{DIV}	frequency divide equals (1, 2, 4, or 8)

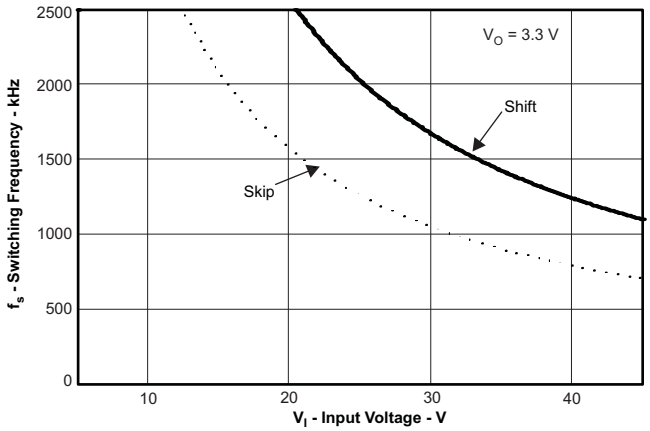


Figure 40. Maximum Switching Frequency vs. Input Voltage

Feature Description (continued)

7.3.15 How to Interface to RT/CLK Pin

The RT/CLK pin can be used to synchronize the regulator to an external system clock. To implement the synchronization feature connect a square wave to the RT/CLK pin through the circuit network shown in Figure 41. The square wave amplitude must transition lower than 0.5 V and higher than 2.2 V on the RT/CLK pin and have an on-time greater than 40 nS and an off-time greater than 40 ns. The synchronization frequency range is 300 kHz to 2200 kHz. The rising edge of the PH will be synchronized to the falling edge of RT/CLK pin signal. The external synchronization circuit should be designed in such a way that the device will have the default frequency set resistor connected from the RT/CLK pin-to-ground should the synchronization signal turn-off. It is recommended to use a frequency set resistor connected as shown in Figure 41 through a 50-Ω resistor-to-ground. The resistor should set the switching frequency close to the external CLK frequency. TI recommends AC-coupling the synchronization signal through a 10-pF ceramic capacitor to RT/CLK pin and a 4-kΩ series resistor. The series resistor reduces PH jitter in heavy load applications when synchronizing to an external clock and in applications which transition from synchronizing to RT mode. The first time the CLK is pulled above the CLK threshold, the device switches from the RT resistor frequency to PLL mode. The internal 0.5-V voltage source is removed and the CLK pin becomes high impedance as the PLL starts to lock onto the external signal. Since there is a PLL on the regulator the switching frequency can be higher or lower than the frequency set with the external resistor. The device transitions from the resistor mode to the PLL mode and then will increase or decrease the switching frequency until the PLL locks onto the CLK frequency within 100 microseconds.

When the device transitions from the PLL to resistor mode, the switching frequency will slow down from the CLK frequency to 150 kHz, then reapply the 0.5-V voltage and the resistor will then set the switching frequency. The switching frequency is divided by 8, 4, 2, and 1 as the voltage ramps from 0 to 0.8 volts on VSENSE pin. The device implements a digital frequency shift to enable synchronizing to an external clock during normal startup and fault conditions. Figure 42, Figure 43 and Figure 44 show the device synchronized to an external system clock in continuous conduction mode (CCM) discontinuous conduction (DCM) and pulse skip mode (PSM).

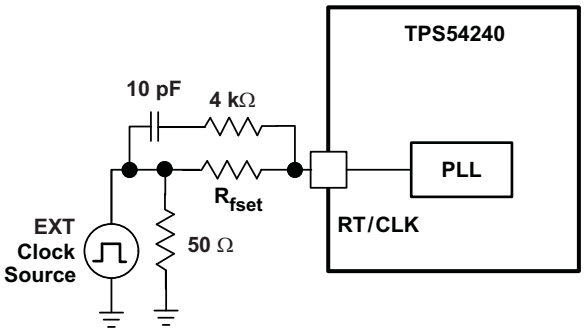


Figure 41. Synchronizing to a System Clock

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Feature Description (continued)

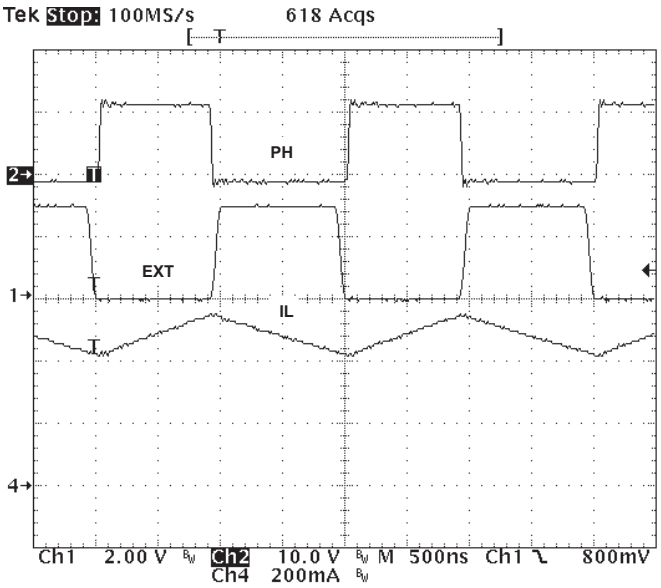


Figure 42. Plot of Synchronizing in CCM

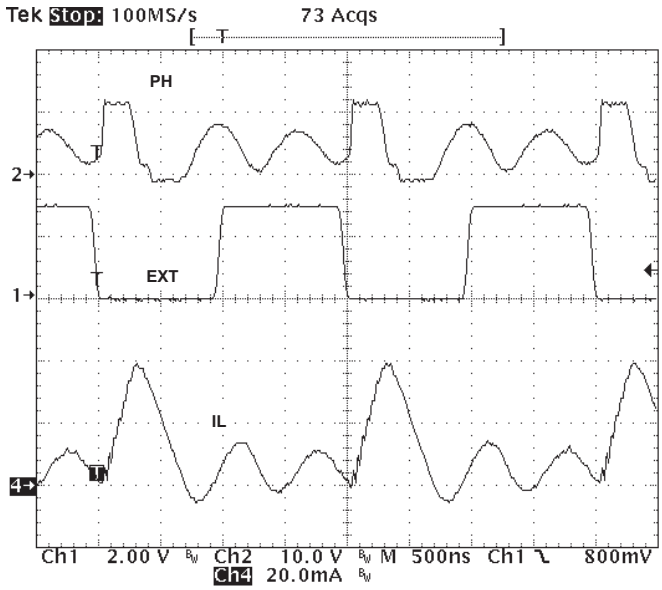


Figure 43. Plot of Synchronizing in DCM

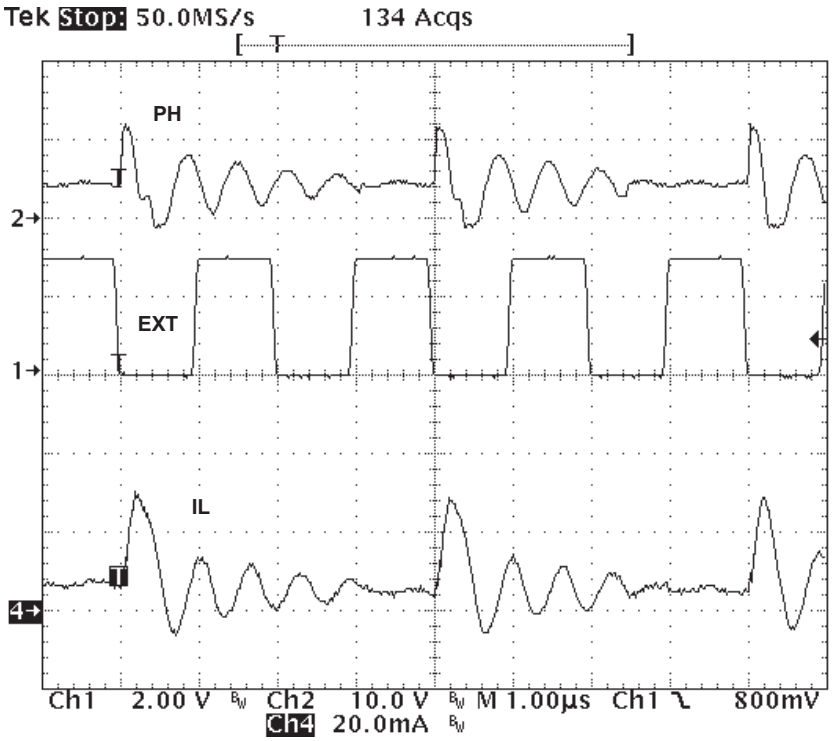


Figure 44. Plot of Synchronizing in PSM

7.3.16 Powergood (PWRGD Pin)

The PWRGD pin is an open-drain output. Once the VSENSE pin is between 94% and 107% of the internal voltage reference, the PWRGD pin is de-asserted and the pin floats. TI recommends using a pullup resistor between the values of 10 and 100 kΩ to a voltage source that is 5.5 V or less. The PWRGD is in a defined state once the VIN input voltage is greater than 1.5 V but with reduced current sinking capability. The PWRGD will achieve full current sinking capability as VIN input voltage approaches 3 V.

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Feature Description (continued)

The PWRGD pin is pulled low when the VSENSE is lower than 92% or greater than 109% of the nominal internal reference voltage. Also, the PWRGD is pulled low, if the UVLO or thermal shutdown are asserted or the EN pin pulled low.

7.3.17 Overvoltage Transient Protection

The TPS54240 incorporates an overvoltage transient protection (OVTP) circuit to minimize voltage overshoot when recovering from output fault conditions or strong unload transients on power supply designs with low-value output capacitance. For example, when the power supply output is overloaded the error amplifier compares the actual output voltage to the internal reference voltage. If the VSENSE pin voltage is lower than the internal reference voltage for a considerable time, the output of the error amplifier will respond by clamping the error amplifier output to a high voltage, thus requesting the maximum output current. Once the condition is removed, the regulator output rises and the error amplifier output transitions to the steady-state duty cycle. In some applications, the power supply output voltage can respond faster than the error amplifier output can respond, this actuality leads to the possibility of an output overshoot. The OVTP feature minimizes the output overshoot, when using a low-value output capacitor, by implementing a circuit to compare the VSENSE pin voltage to OVTP threshold which is 109% of the internal voltage reference. If the VSENSE pin voltage is greater than the OVTP threshold, the high-side MOSFET is disabled, preventing current from flowing to the output and minimizing output overshoot. When the VSENSE voltage drops lower than the OVTP threshold, the high-side MOSFET is allowed to turn on at the next clock cycle.

7.3.18 Thermal Shutdown

The device implements an internal thermal shutdown to protect itself if the junction temperature exceeds 182°C. The thermal shutdown forces the device to stop switching when the junction temperature exceeds the thermal trip threshold. Once the die temperature decreases below 182°C, the device reinitiates the power-up sequence by discharging the SS/TR pin.

7.3.19 Small Signal Model for Loop Response

Figure 45 shows an equivalent model for the TPS54240 control loop which can be modeled in a circuit simulation program to check frequency response and dynamic load response. The error amplifier is a transconductance amplifier with a gm_{EA} of 310 µA/V. The error amplifier can be modeled using an ideal voltage controlled current source. The resistor R_o and capacitor C_o model the open-loop gain and frequency response of the amplifier. The 1-mV AC voltage source between the nodes A and B effectively breaks the control loop for the frequency response measurements. Plotting C/A shows the small signal response of the frequency compensation. Plotting A/B shows the small signal response of the overall loop. The dynamic loop response can be checked by replacing R_L with a current source with the appropriate load step amplitude and ste- rate in a time domain analysis. This equivalent model is only valid for continuous conduction mode designs.

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Feature Description (continued)

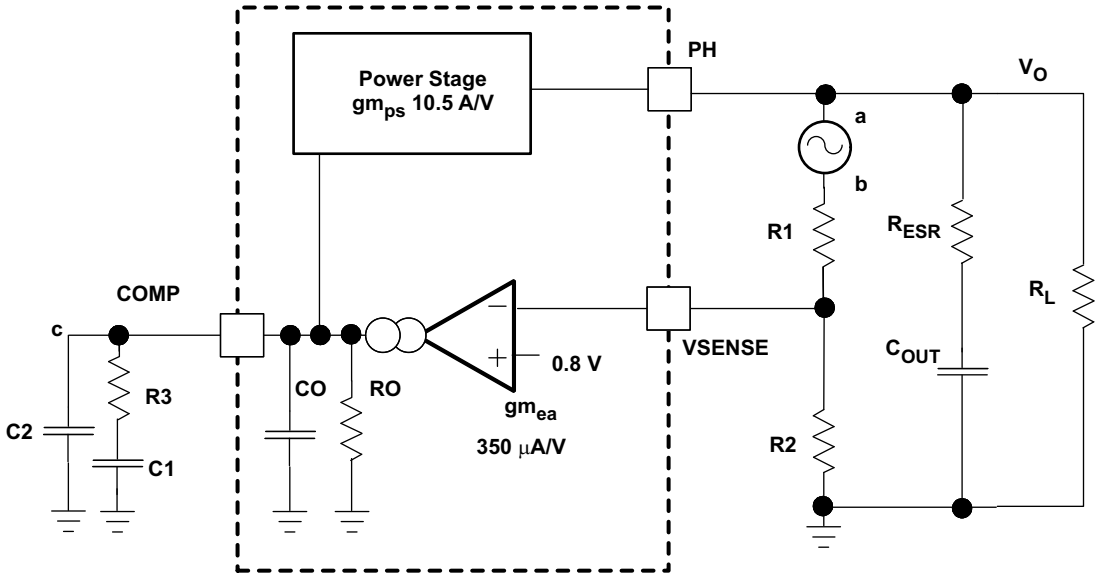


Figure 45. Small Signal Model for Loop Response

7.3.20 Simple Small Signal Model for Peak Current Mode Control

Figure 46 describes a simple small signal model that can be used to understand how to design the frequency compensation. The TPS54240 power stage can be approximated to a voltage-controlled current source (duty cycle modulator) supplying current to the output capacitor and load resistor. The control to output transfer function is shown in Equation 14 and consists of a DC gain, one dominant pole, and one ESR zero. The quotient of the change in switch current and the change in COMP pin voltage (node C in Figure 45) is the power stage transconductance. The gm_{PS} for the TPS54240 is 10.5 A/V. The low-frequency gain of the power stage frequency response is the product of the transconductance and the load resistance as shown in Equation 15.

As the load current increases and decreases, the low-frequency gain decreases and increases, respectively. This variation with the load may seem problematic at first glance, but fortunately the dominant pole moves with the load current (see Equation 16). The combined effect is highlighted by the dashed line in the right half of Figure 46. As the load current decreases, the gain increases and the pole frequency lowers, keeping the 0-dB crossover frequency the same for the varying load conditions which makes it easier to design the frequency compensation. The type of output capacitor chosen determines whether the ESR zero has a profound effect on the frequency compensation design. Using high-ESR aluminum electrolytic capacitors may reduce the number frequency compensation components needed to stabilize the overall loop because the phase margin increases from the ESR zero at the lower frequencies (see Equation 17).

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Feature Description (continued)

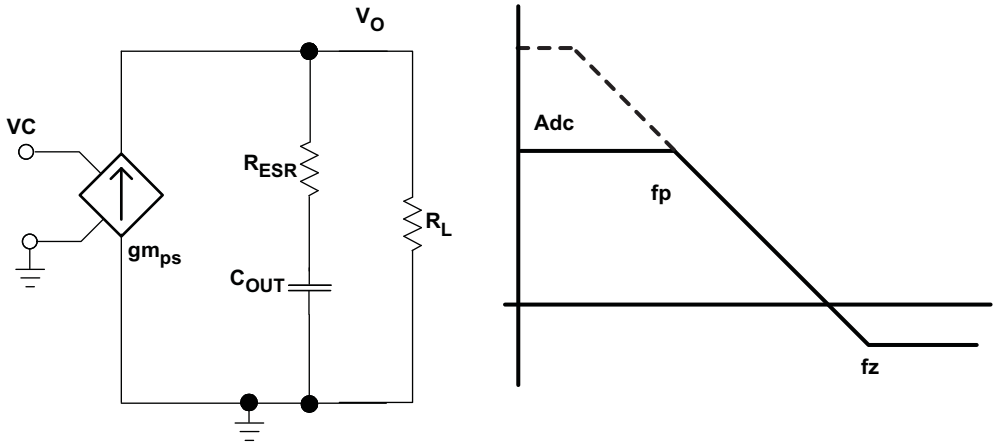


Figure 46. Simple Small Signal Model and Frequency Response for Peak Current Mode Control

$$\frac{V_{OUT}}{V_C} = Adc \times \frac{\left(1 + \frac{s}{2\pi \times f_Z}\right)}{\left(1 + \frac{s}{2\pi \times f_P}\right)} \quad (14)$$

$$Adc = gm_{ps} \times R_L \quad (15)$$

$$f_P = \frac{1}{C_{OUT} \times R_L \times 2\pi} \quad (16)$$

$$f_Z = \frac{1}{C_{OUT} \times R_{ESR} \times 2\pi} \quad (17)$$

7.3.21 Small Signal Model for Frequency Compensation

The TPS54240 uses a transconductance amplifier for the error amplifier and readily supports three of the commonly-used frequency compensation circuits. Compensation circuits Type 2A, Type 2B, and Type 1 are shown in Figure 47. Type 2 circuits most likely implemented in high-bandwidth, power supply designs using low-ESR output capacitors. The Type 1 circuit is used with power supply designs with high-ESR aluminum electrolytic or tantalum capacitors.. Equation 18 and Equation 19 show how to relate the frequency response of the amplifier to the small signal model in Figure 47. The open-loop gain and bandwidth are modeled using the R_O and C_O shown in Figure 47. See *Application Information* for a design example using a Type 2A network with a low-ESR output capacitor.

Equation 18 through Equation 27 are provided as a reference for those who prefer to compensate using the preferred methods. Those who prefer to use prescribed method use the method outlined in the *Application Information and Implementation* section or use switched information.

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Feature Description (continued)

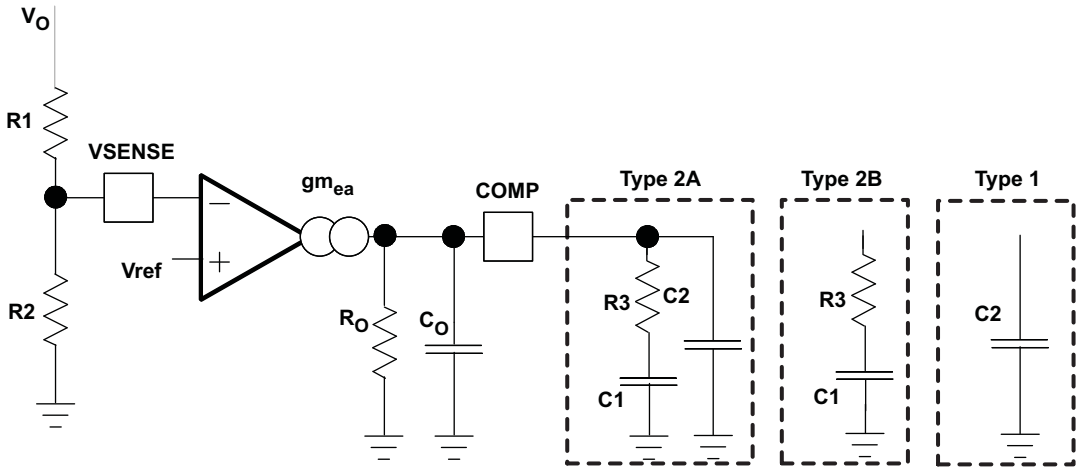


Figure 47. Types of Frequency Compensation

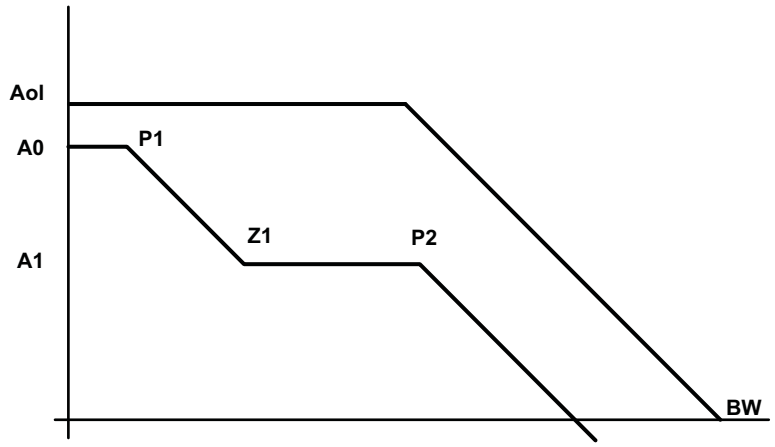


Figure 48. Frequency Response of the Type 2A and Type 2B Frequency Compensation

$$Ro = \frac{AoI(V/V)}{gm_{ea}} \quad (18)$$

$$C_O = \frac{gm_{ea}}{2\pi \times BW\ (Hz)} \quad (19)$$

$$EA = A0 \times \frac{\left(1 + \frac{s}{2\pi \times f_{Z1}}\right)}{\left(1 + \frac{s}{2\pi \times f_{P1}}\right) \times \left(1 + \frac{s}{2\pi \times f_{P2}}\right)} \quad (20)$$

$$A0 = gm_{ea} \times Ro \times \frac{R2}{R1 + R2} \quad (21)$$

$$A1 = gm_{ea} \times Ro \,||\, R3 \times \frac{R2}{R1 + R2} \quad (22)$$

$$P1 = \frac{1}{2\pi \times Ro \times C1} \quad (23)$$

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Feature Description (continued)

$$Z1 = \frac{1}{2\pi \times R3 \times C1} \quad (24)$$

$$P2 = \frac{1}{2\pi \times R3 \,||\, R_O \times (C2 + C_O)} \text{ type 2a} \quad (25)$$

$$P2 = \frac{1}{2\pi \times R3 \,||\, R_O \times C_O} \text{ type 2b} \quad (26)$$

$$P2 = \frac{1}{2\pi \times R_O \times (C2 + C_O)} \text{ type 1} \quad (27)$$

7.4 Device Functional Modes

7.4.1 Operation Near Minimum VIN ($V_{(VIN)}$) = < 3.5 V)

The TPS54240 is designed to operate with input voltage above 3.5 V. The typical VIN UVLO threshold is 2.5 V and the device may operate at input voltages down to the UVLO voltage. At input voltages below the UVLO voltage, the device does not switch. If an external resistor divider pulls the EN pin up to VIN or the EN pin is floating, when VIN passes the UVLO threshold the device becomes active. When the device is active, switching begins and the soft-start sequence initiates. The TPS54240 ramps up the output voltage at the soft-start time determined by the external capacitance on the SS/TR pin.

7.4.2 Operation With EN Control

The enabled threshold voltage is 1.2 V typical. With EN held below the threshold voltage the device is shut down and switching is inhibited even if the VIN voltage is above its UVLO threshold. The IC quiescent current decreases to a minimum in this state. If the EN pin voltage is increased above its threshold while the VIN voltage is also above its UVLO threshold, the device becomes active. When the device is active, switching begins and the soft-start sequence initiates. The TPS54240 ramps up the output voltage at the soft-start time determined by the external capacitance on the SS/TR pin.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS54240 device is a 42-V, 2.5-A, step-down regulator with an integrated high-side MOSFET. This device typically converts a higher DC voltage to a lower DC voltage with a maximum available output current of 2.5 A. Example applications are 12-V and 24-V industrial, automotive and communication power systems. Use the following design procedure to select component values for the TPS54240 device. This procedure illustrates the design of a high-frequency switching regulator using ceramic output capacitors. The Excel™ spreadsheet (SLVC432) located on the product page can help on all calculations. Alternatively, use the WEBENCH software to generate a complete design. The WEBENCH software uses an iterative design procedure and accesses a comprehensive database of components when generating a design.

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8.2 Typical Application

8.2.1 TPS54240 3.3-V Output Design

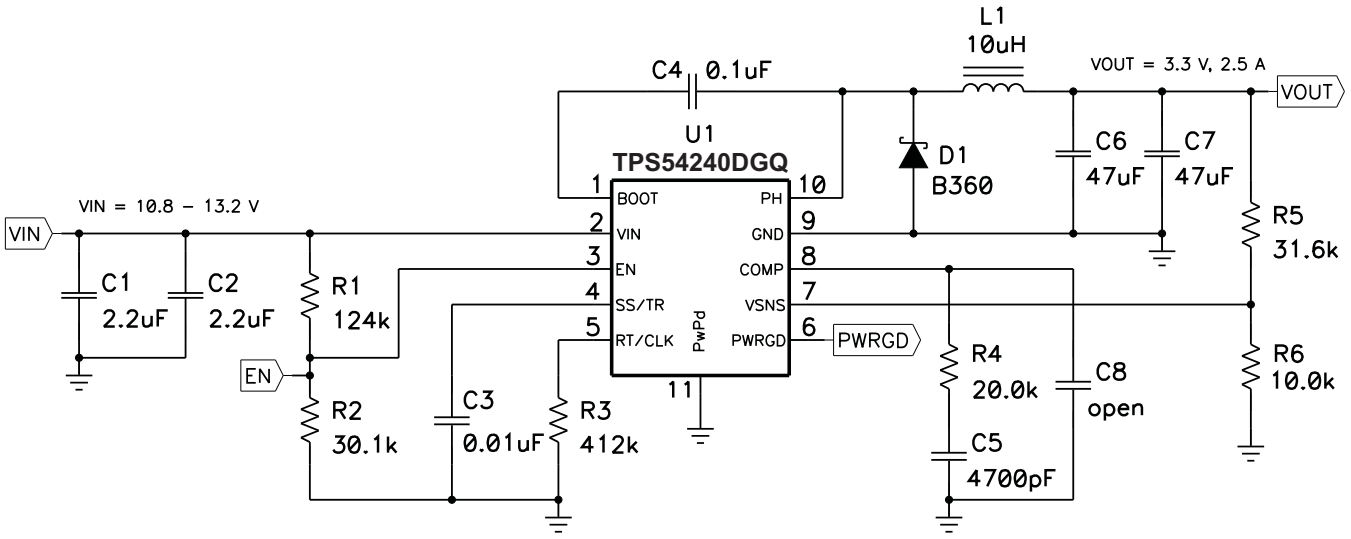


Figure 49. 3.3-V Output TPS54240 Design Example

8.2.1.1 Design Requirements

This example details the design of a high-frequency switching regulator design using ceramic output capacitors. A few parameters must be known in order to start the design process. These parameters are typically determined at the system level. For this example, we will start with the following known parameters:

DESIGN PARAMETERS	VALUE
Output Voltage	3.3 V
Transient Response 0 to 1.5-A load step	ΔVout = 3 %
Maximum Output Current	2.5 A
Input Voltage	12 V nom. 10.8 V to 13.2 V
Output Voltage Ripple	1% of Vout
Start Input Voltage (rising VIN)	6.25 V
Stop Input Voltage (falling VIN)	5.9 V

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Selecting the Switching Frequency

The first step is to decide on a switching frequency for the regulator. Typically, the user will want to choose the highest switching frequency possible since this will produce the smallest solution size. The high-switching frequency allows for lower valued inductors and smaller output capacitors compared to a power supply that switches at a lower frequency. The switching frequency that can be selected is limited by the minimum on-time of the internal power switch, the input voltage and the output voltage and the frequency shift limitation.

Equation 12 and Equation 13 must be used to find the maximum switching frequency for the regulator, choose the lower value of the two equations. Switching frequencies higher than these values will result in pulse skipping or the lack of overcurrent protection during a short circuit.

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The typical minimum on time, t_{onmin}, is 135 ns for the TPS54240. For this example, the output voltage is 3.3 V and the maximum input voltage is 13.2 V, which allows for a maximum switch frequency up to 2247 kHz when including the inductor resistance, on resistance output current and diode voltage in Equation 12. To ensure overcurrent runaway is not a concern during short circuits in your design use Equation 13 or the solid curve in Figure 40 to determine the maximum switching frequency. With a maximum input voltage of 13.2 V, assuming a diode voltage of 0.7 V, inductor resistance of 26 mΩ, switch resistance of 200 mΩ, a current limit value of 3.5 A and a short circuit output voltage of 0.2 V. The maximum switching frequency is approximately 4449 kHz.

For this design, a much lower switching frequency of 300 kHz is used. To determine the timing resistance for a given switching frequency, use Equation 11 or the curve in Figure 39.

The switching frequency is set by resistor R3 shown in Figure 49 For 300-kHz operation a 412-kΩ resistor is required.

8.2.1.2.2 Output Inductor Selection (L_O)

To calculate the minimum value of the output inductor, use Equation 28.

K_{IND} is a coefficient that represents the amount of inductor ripple current relative to the maximum output current.

The inductor ripple current will be filtered by the output capacitor. Therefore, choosing high-inductor ripple currents will impact the selection of the output capacitor since the output capacitor must have a ripple current rating equal to or greater than the inductor ripple current. In general, the inductor ripple value is at the discretion of the designer; however, the following guidelines may be used.

For designs using low ESR output capacitors such as ceramics, a value as high as K_{IND} = 0.3 may be used. When using higher ESR output capacitors, K_{IND} = 0.2 yields better results. Since the inductor ripple current is part of the PWM control system, the inductor ripple current should always be greater than 150 mA for dependable operation. In a wide-input voltage regulator, it is best to choose an inductor ripple current on the larger side. This allows the inductor to still have a measurable ripple current with the input voltage at its minimum.

For this design example, use K_{IND} = 0.3 and the minimum inductor value is calculated to be 11 µH. For this design, a nearest standard value was chosen: 10 µH. For the output filter inductor, it is important that the RMS current and saturation current ratings not be exceeded. The RMS and peak inductor current can be found from Equation 30 and Equation 31.

For this design, the RMS inductor current is 2.51 A and the peak inductor current is 2.913 A. The chosen inductor is a Coilcraft MSS1038-103NLB . It has a saturation current rating of 4.52 A and an RMS current rating of 4.05 A.

As the equation set demonstrates, lower ripple currents will reduce the output voltage ripple of the regulator but will require a larger value of inductance. Selecting higher ripple currents will increase the output voltage ripple of the regulator but allow for a lower inductance value.

The current flowing through the inductor is the inductor ripple current plus the output current. During power-up, faults or transient load conditions, the inductor current can increase above the calculated peak inductor current level calculated above. In transient conditions, the inductor current can increase up to the switch current limit of the device. For this reason, the most conservative approach is to specify an inductor with a saturation current rating equal to or greater than the switch current limit rather than the peak inductor current.

$$\text{Lo min} = \frac{\text{Vinmax} - \text{Vout}}{\text{Io} \times K_{IND}} \times \frac{\text{Vout}}{\text{Vinmax} \times f\text{sw}} \tag{28}$$

$$I_{RIPPLE} = \frac{V_{OUT} \times (\text{Vinmax} - V_{OUT})}{\text{Vinmax} \times L_O \times f_{SW}} \tag{29}$$

$$I_{L(rms)} = \sqrt{(I_O)^2 + \frac{1}{12} \times \left(\frac{V_{OUT} \times (\text{Vinmax} - V_{OUT})}{\text{Vinmax} \times L_O \times f_{SW}} \right)^2} \tag{30}$$

$$ILpeak = Iout + \frac{Iripple}{2} \tag{31}$$

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8.2.1.2.3 Output Capacitor

There are three primary considerations for selecting the value of the output capacitor. The output capacitor will determine the modulator pole, the output voltage ripple, and how the regulators responds to a large change in load current. The output capacitance needs to be selected based on the more stringent of these three criteria.

The desired response to a large change in the load current is the first criteria. The output capacitor needs to supply the load with current when the regulator cannot. This situation would occur if there are desired hold-up times for the regulator where the output capacitor must hold the output voltage above a certain level for a specified amount of time after the input power is removed. The regulator also will temporarily not be able to supply sufficient output current if there is a large, fast increase in the current needs of the load such as transitioning from no load to a full load. The regulator usually needs two or more clock cycles for the control loop to see the change in load current and output voltage and adjust the duty cycle to react to the change. The output capacitor must be sized to supply the extra current to the load until the control loop responds to the load change. The output capacitance must be large enough to supply the difference in current for two clock cycles while only allowing a tolerable amount of droop in the output voltage. Equation 32 shows the minimum output capacitance necessary to accomplish this.

Where ΔIout is the change in output current, $f$sw is the regulators switching frequency and ΔVout is the allowable change in the output voltage. For this example, the transient load response is specified as a 3% change in Vout for a load step from 1.5 A to 2.5 A (full load). For this example, ΔIout = 2.5-1.5 = 1.0 A and ΔVout = 0.03 × 3.3 = 0.099 V. Using these numbers gives a minimum capacitance of 67 µF. This value does not take the ESR of the output capacitor into account in the output voltage change. For ceramic capacitors, the ESR is usually small enough to ignore in this calculation. Aluminum electrolytic and tantalum capacitors have higher ESR that should be taken into account.

The catch diode of the regulator cannot sink current so any stored energy in the inductor will produce an output voltage overshoot when the load current rapidly decreases, see Figure 50. The output capacitor must also be sized to absorb energy stored in the inductor when transitioning from a high load current to a lower load current. The excess energy that gets stored in the output capacitor will increase the voltage on the capacitor. The capacitor must be sized to maintain the desired output voltage during these transient periods. Equation 33 is used to calculate the minimum capacitance to keep the output voltage overshoot to a desired value. Where L is the value of the inductor, I_{OH} is the output current under heavy load, I_{OL} is the output under light load, Vf is the final peak output voltage, and Vi is the initial capacitor voltage. For this example, the worst case load step will be from 2.5 A to 1.5 A. The output voltage will increase during this load transition and the stated maximum in our specification is 3 % of the output voltage. This will make Vf = 1.03 × 3.3 = 3.399 V. Vi is the initial capacitor voltage which is the nominal output voltage of 3.3 V. Using these numbers in Equation 33 yields a minimum capacitance of 60 µF.

Equation 34 calculates the minimum output capacitance needed to meet the output voltage ripple specification. Where fsw is the switching frequency, $V_{oripple}$ is the maximum allowable output voltage ripple, and I_{ripple} is the inductor ripple current. Equation 34 yields 12 µF.

Equation 35 calculates the maximum ESR an output capacitor can have to meet the output voltage ripple specification. Equation 35 indicates the ESR should be less than 36 mΩ.

The most stringent criteria for the output capacitor is 67 µF of capacitance to keep the output voltage in regulation during an load transient.

Additional capacitance de-ratings for aging, temperature and DC bias should be factored in which will increase this minimum value. For this example, 2 x 47-µF, 10-V ceramic capacitors with 3 mΩ of ESR will be used. The derated capacitance is 72.4 µF, above the minimum required capacitance of 67 µF.

Capacitors generally have limits to the amount of ripple current they can handle without failing or producing excess heat. An output capacitor that can support the inductor ripple current must be specified. Some capacitor data sheets specify the Root Mean Square (RMS) value of the maximum ripple current. Equation 36 can be used to calculate the RMS ripple current the output capacitor needs to support. For this application, Equation 36 yields 238 mA.

$$\text{Cout} > \frac{2 \times \Delta\text{Iout}}{f\text{sw} \times \Delta\text{Vout}} \tag{32}$$

$$Cout > Lo \times \frac{\left(Ioh^2 - Iol^2\right)}{\left(Vf^2 - Vi^2\right)} \quad (33)$$

$$Cout > \frac{1}{8 \times fsw} \times \frac{1}{\frac{V_{ORIPPLE}}{I_{RIPPLE}}} \quad (34)$$

$$R_{ESR} < \frac{V_{ORIPPLE}}{I_{RIPPLE}} \quad (35)$$

$$Icorms = \frac{Vout \times (Vin\ max - Vout)}{\sqrt{12} \times Vin\ max \times Lo \times fsw} \quad (36)$$

8.2.1.2.4 Catch Diode

The TPS54240 requires an external catch diode between the PH pin and GND. The selected diode must have a reverse voltage rating equal to or greater than Vinmax. The peak current rating of the diode must be greater than the maximum inductor current. The diode should also have a low-forward voltage. Schottky diodes are typically a good choice for the catch diode due to their low-forward voltage. The lower the forward voltage of the diode, the higher the efficiency of the regulator.

Typically, the higher the voltage and current ratings the diode has, the higher the forward voltage will be. Although the design example has an input voltage up to 13.2 V, a diode with a minimum of 60-V reverse voltage is selected.

For the example design, the B360B-13-F Schottky diode is selected for its lower-forward voltage and it comes in a larger package size which has good thermal characteristics over small devices. The typical forward voltage of the B360B-13-F is 0.70 volts.

The diode must also be selected with an appropriate power rating. The diode conducts the output current during the off-time of the internal power switch. The off-time of the internal switch is a function of the maximum input voltage, the output voltage, and the switching frequency. The output current during the off-time is multiplied by the forward voltage of the diode which equals the conduction losses of the diode. At higher switch frequencies, the AC losses of the diode need to be taken into account. The AC losses of the diode are due to the charging and discharging of the junction capacitance and reverse recovery. Equation 37 is used to calculate the total power dissipation, conduction losses plus SC losses, of the diode.

The B360B-13-F has a junction capacitance of 200 pF. Using Equation 37, the selected diode will dissipate 1.32 Watts.

If the power supply spends a significant amount of time at light load currents or in sleep mode consider using a diode which has a low leakage current and slightly higher-forward voltage drop.

$$Pd = \frac{(Vin\ max - Vout) \times Iout \times Vfd}{Vin\ max} + \frac{Cj \times fsw \times \left(Vin + Vfd\right)^2}{2} \quad (37)$$

8.2.1.2.5 Input Capacitor

The TPS54240 requires a high-quality ceramic, type X5R or X7R, input-decoupling capacitor of at least 3 µF of effective capacitance, and in some applications, a bulk capacitance. The effective capacitance includes any DC bias effects. The voltage rating of the input capacitor must be greater than the maximum input voltage. The capacitor must also have a ripple current rating greater than the maximum input current ripple of the TPS54240. The input ripple current can be calculated using Equation 38.

The value of a ceramic capacitor varies significantly over temperature and the amount of DC bias applied to the capacitor. The capacitance variations due to temperature can be minimized by selecting a dielectric material that is stable over temperature. X5R and X7R ceramic dielectrics are usually selected for power-regulator capacitors because they have a high capacitance-to-volume ratio and are fairly stable over temperature. The output capacitor must also be selected with the DC bias taken into account. The capacitance value of a capacitor decreases as the DC bias across a capacitor increases.

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For this example design, a ceramic capacitor with at least a 60-V voltage rating is required to support the maximum input voltage. Common standard ceramic capacitor voltage ratings include 4 V, 6.3 V, 10 V, 16 V, 25 V, 50 V or 100 V, so a 100-V capacitor should be selected. For this example, two 2.2-µF, 100-V capacitors in parallel have been selected. Table 1 shows a selection of high voltage capacitors. The input capacitance value determines the input ripple voltage of the regulator. The input voltage ripple can be calculated using Equation 39. Using the design example values, Ioutmax = 2.5 A, Cin = 4.4 µF, $f$sw = 300 kHz, yields an input voltage ripple of 206 mV and a rms input ripple current of 1.15 A.

$$\text{Icirms} = \text{Iout} \times \sqrt{\frac{\text{Vout}}{\text{Vin min}}} \times \frac{(\text{Vin min} - \text{Vout})}{\text{Vin min}} \tag{38}$$

$$\Delta\text{Vin} = \frac{\text{Iout max} \times 0.25}{\text{Cin} \times f\text{sw}} \tag{39}$$

Table 1. Capacitor Types

VENDOR	VALUE (µF)	EIA Size	VOLTAGE	DIALECTRIC	COMMENTS
Murata	1.0 to 2.2	1210	100 V	X7R	GRM32 series
	1.0 to 4.7		50 V		
	1.0	1206	100 V		GRM31 series
	1.0 to 2.2		50 V		
Vishay	1.0 10 1.8	2220	50 V		VJ X7R series
	1.0 to 1.2		100 V		
	1.0 to 3.9	2225	50 V		
	1.0 to 1.8		100 V		
TDK	1.0 to 2.2	1812	100 V		C series C4532
	1.5 to 6.8		50 V		
	1.0. to 2.2	1210	100 V		C series C3225
	1.0 to 3.3		50 V		
AVX	1.0 to 4.7	1210	50 V		X7R dielectric series
	1.0		100 V		
	1.0 to 4.7	1812	50 V		
	1.0 to 2.2		100 V		

8.2.1.2.6 Slow-Start Capacitor

The slow-start capacitor determines the minimum amount of time it will take for the output voltage to reach its nominal programmed value during power-up. This is useful if a load requires a controlled voltage slew rate. This is also used if the output capacitance is large and would require large amounts of current to quickly charge the capacitor to the output voltage level. The large currents necessary to charge the capacitor may make the TPS54240 reach the current limit or excessive current draw from the input power supply may cause the input voltage rail to sag. Limiting the output voltage slew rate solves both of these problems.

The slow-start time must be long enough to allow the regulator to charge the output capacitor up to the output voltage without drawing excessive current. Equation 40 can be used to find the minimum slow-start time, tss, necessary to charge the output capacitor, Cout, from 10% to 90% of the output voltage, Vout, with an average slow-start current of Issavg. In the example, to charge the effective output capacitance of 72.4 µF up to 3.3 V while only allowing the average output current to be 1 A would require a 0.19-ms slow-start time.

Once the slow-start time is known, the slow-start capacitor value can be calculated using Equation 6. For the example circuit, the slow-start time is not too critical since the output capacitor value is 2 x 47 µF which does not require much current to charge to 3.3 V. The example circuit has the slow start-time set to an arbitrary value of 3.5 ms which requires a 8.75 nF slow-start capacitor. For this design, the next larger standard value of 10 nF is used.

$$\text{tss} > \frac{\text{Cout} \times \text{Vout} \times 0.8}{\text{Issavg}} \tag{40}$$

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8.2.1.2.7 Bootstrap Capacitor Selection

A 0.1-µF ceramic capacitor must be connected between the BOOT and PH pins for proper operation. TI recommends using a ceramic capacitor with X5R or better grade dielectric. The capacitor should have a 10-V or higher voltage rating.

8.2.1.2.8 Undervoltage Lock Out Set Point

The Undervoltage Lock Out (UVLO) can be adjusted using an external voltage divider on the EN pin of the TPS54240. The UVLO has two thresholds, one for power-up when the input voltage is rising, and one for power-down or brown outs when the input voltage is falling. For the example design, the supply should turn on and start switching once the input voltage increases above 6.25 V (enabled). After the regulator starts switching, it should continue to do so until the input voltage falls below 5.9 V (UVLO stop).

The programmable UVLO and enable voltages are set using the resistor divider of R1 and R2 between Vin and ground to the EN pin. Equation 2 through Equation 3 can be used to calculate the resistance values necessary. For the example application, a 124 kΩ between Vin and EN (R1) and a 30.1 kΩ between EN and ground (R2) are required to produce the 6.25 and 5.9 volt start and stop voltages.

8.2.1.2.9 Output Voltage And Feedback Resistors Selection

The voltage divider of R5 and R6 is used to set the output voltage. For the example design, 10.0 kΩ was selected for R6. Using Equation 1, R5 is calculated as 31.25 kΩ. The nearest standard 1% resistor is 31.6 kΩ. Due to current leakage of the VSENSE pin, the current flowing through the feedback network should be greater than 1 µA to maintain the output voltage accuracy. This requirement makes the maximum value of R2 equal to 800 kΩ. Choosing higher resistor values will decrease quiescent current and improve efficiency at low-output currents but may introduce noise immunity problems.

8.2.1.2.10 Compensation

There are several methods used to compensate DC - DC regulators. The method presented here is easy to calculate and ignores the effects of the slope compensation that is internal to the device. Because the slope compensation is ignored, the actual cross-over frequency will usually be lower than the cross-over frequency used in the calculations. This method assumes the cross-over frequency is between the modulator pole and the ESR zero and the ESR zero is at least 10 times greater the modulator pole. Use SwitcherPro software for a more accurate design.

To get started, the modulator pole, fpmod, and the ESR zero, fz1 must be calculated using Equation 41 and Equation 42. For Cout, use a derated value of 40 µF. Use equations Equation 43 and Equation 44, to estimate a starting point for the crossover frequency, fco, to design the compensation. For the example design, fpmod is 1206 Hz and fzmod is 530.5 kHz. Equation 43 is the geometric mean of the modulator pole and the esr zero and Equation 44 is the mean of modulator pole and the switching frequency. Equation 43 yields 25.3 kHz and Equation 44 gives 13.4 kHz. Use the lower value of Equation 43 or Equation 44 for an initial crossover frequency. For this example, a higher fco is desired to improve transient response. the target fco is 35.0 kHz. Next, the compensation components are calculated. A resistor-in-series with a capacitor is used to create a compensating zero. A capacitor in parallel to these two components forms the compensating pole.

$$fp\ \text{mod} = \frac{\text{Ioutmax}}{2 \times \pi \times \text{Vout} \times \text{Cout}} \tag{41}$$

$$fz\ \text{mod} = \frac{1}{2 \times \pi \times \text{Resr} \times \text{Cout}} \tag{42}$$

$$f_{co} = \sqrt{f_p \text{mod} \times f_z \text{mod}} \tag{43}$$

$$f_{co} = \sqrt{f_p \text{mod} \times \frac{f_{sw}}{2}} \tag{44}$$

To determine the compensation resistor, R4, use Equation 45. Assume the power stage transconductance, gmps, is 10.5 A/V. The output voltage, Vo, reference voltage, VREF, and amplifier transconductance, gmea, are 3.3 V, 0.8 V and 310 µA/V, respectively. R4 is calculated to be 20.2 kΩ, use the nearest standard value of 20.0 kΩ. Use Equation 46 to set the compensation zero to the modulator pole frequency. Equation 46 yields 4740 pF for compensating capacitor C5, a 4700 pF is used for this design.

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$$R4 = \left(\frac{2 \times \pi \times f_{co} \times C_{out}}{gmps} \right) \times \left(\frac{V_{out}}{V_{ref} \times gmea} \right) \quad (45)$$

$$C5 = \frac{1}{2 \times \pi \times R4 \times f_{p}mod} \quad (46)$$

A compensation pole can be implemented if desired using an additional capacitor C8 in parallel with the series combination of R4 and C5. Use the larger value of Equation 47 and Equation 48 to calculate the C8, to set the compensation pole. C8 is not used for this design example.

$$C8 = \frac{C_o \times Resr}{R4} \quad (47)$$

$$C8 = \frac{1}{R4 \times f_{sw} \times \pi} \quad (48)$$

8.2.1.2.11 Discontinuous Mode And Eco-Mode Boundary

With an input voltage of 12 V, the power supply enters discontinuous mode when the output current is less than 337 mA. The power supply enters Eco-Mode when the output current is lower than 5 mA.

The input current draw at no load is 392 µA.

8.2.1.2.12 Power Dissipation Estimate

The following formulas show how to estimate the IC power dissipation under continuous conduction mode (CCM) operation. These equations should not be used if the device is working in discontinuous conduction mode (DCM).

The power dissipation of the IC includes conduction loss (Pcon), switching loss (Psw), gate drive loss (Pgd) and supply current (Pq).

$$Pcon = Io^2 \times R_{DS(on)} \times \frac{Vout}{Vin} \quad (49)$$

$$Psw = Vin^2 \times fsw \times Io \times 0.25 \times 10^{-9} \quad (50)$$

$$Pgd = Vin \times 3 \times 10^{-9} \times fsw \quad (51)$$

$$Pq = 116 \times 10^{-6} \times Vin \quad (52)$$

Where:

Iout is the output current (A).
$R_{DS(on)}$ is the on-resistance of the high-side MOSFET (Ω).
Vout is the output voltage (V).
Vin is the input voltage (V).
fsw is the switching frequency (Hz).

So

$$Ptot = Pcon + Psw + Pgd + Pq \quad (53)$$

For given T_A,

$$TJ = TA + Rth \times Ptot \quad (54)$$

For given T_{JMAX} = 150°C

$$TAmax = TJmax - Rth \times Ptot \quad (55)$$

Where:

Ptot is the total device power dissipation (W).
T_A is the ambient temperature (°C).
T_J is the junction temperature (°C).
Rth is the thermal resistance of the package (°C/W).
T_{JMAX} is maximum junction temperature (°C).
T_{AMAX} is maximum ambient temperature (°C).

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There will be additional power losses in the regulator circuit due to the inductor AC and DC losses, the catch diode and trace resistance that will impact the overall efficiency of the regulator.

8.2.1.3 Application Curves

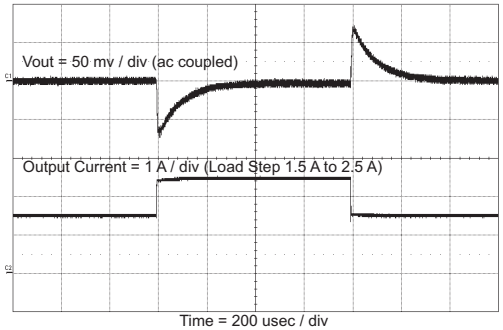


Figure 50. Load Transient

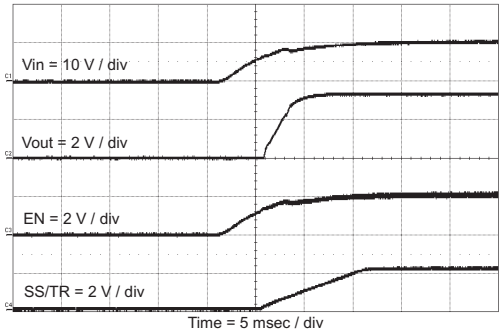


Figure 51. Startup With VIN

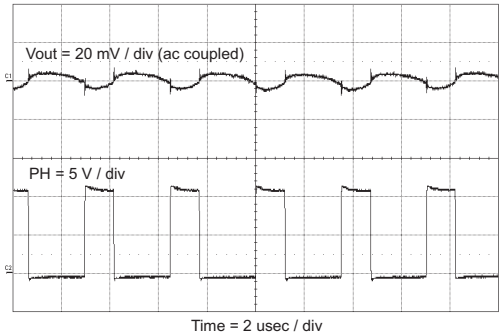


Figure 52. Output Ripple, CCM

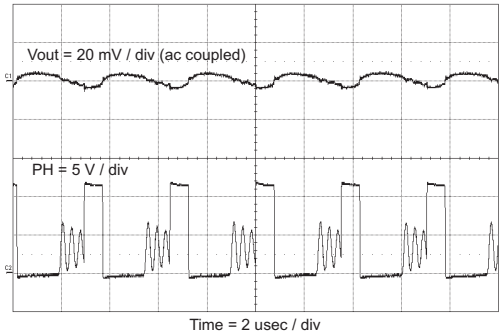


Figure 53. Output Ripple, DCM

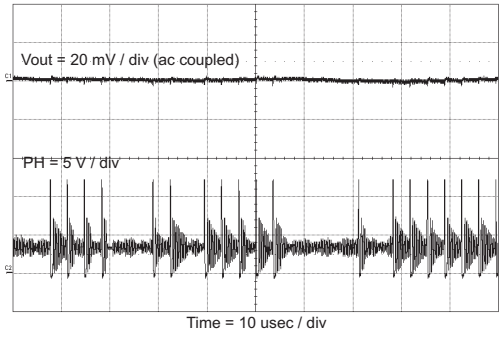


Figure 54. Output Ripple, PSM

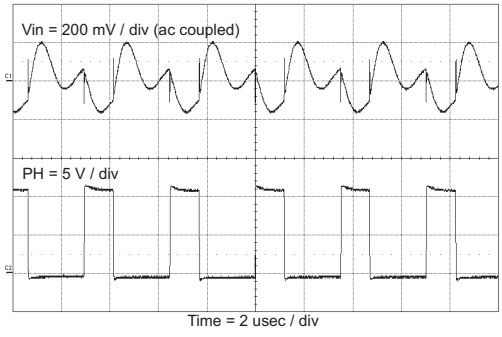


Figure 55. Input Ripple, CCM

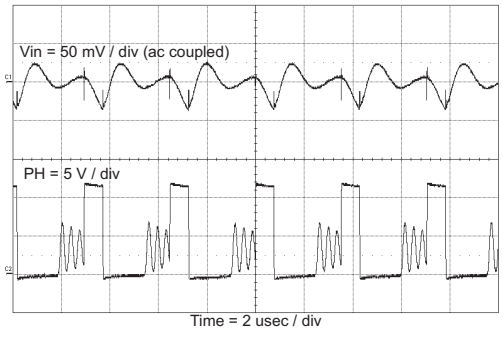


Figure 56. Input Ripple, DCM

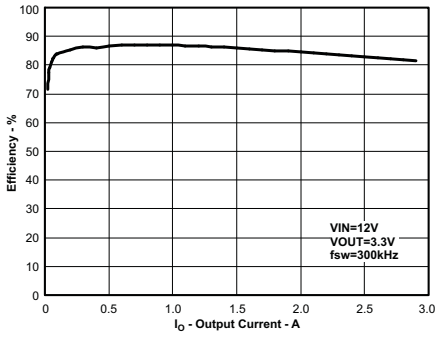


Figure 57. Efficiency vs Load Current

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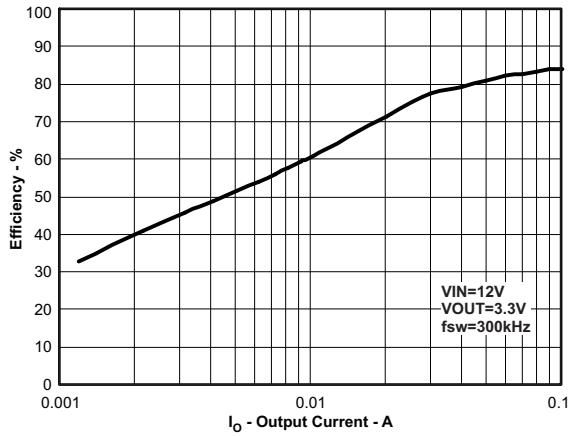


Figure 58. Light Load Efficiency

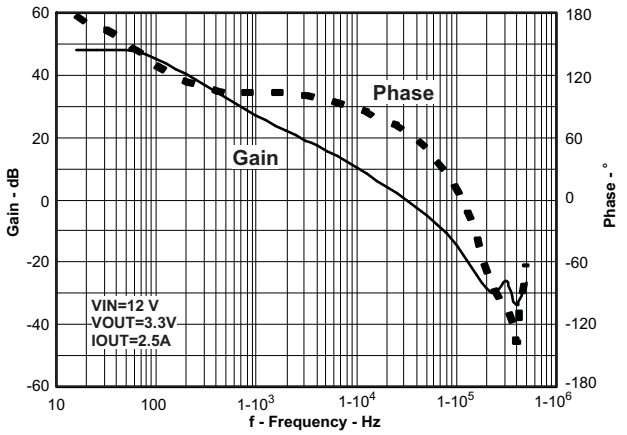


Figure 59. Overall Loop Frequency Response

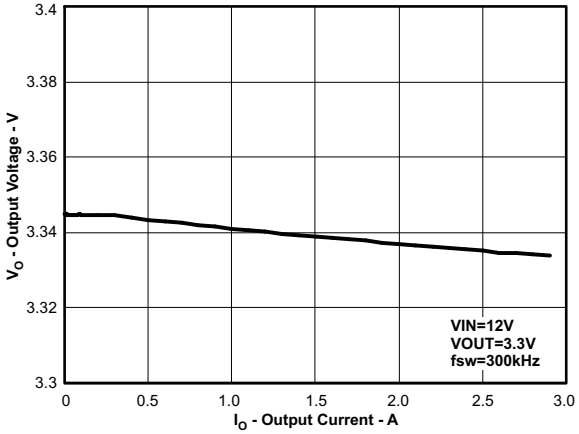


Figure 60. Regulation vs Load Current

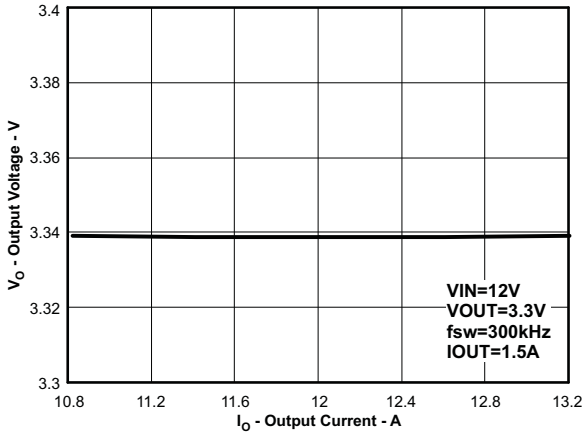


Figure 61. Regulation vs Input Voltage

8.2.2 TPS54240 Inverting Power Supply

This application circuit shows how to use the TPS54240 to convert a positive-input voltage to a negative-output voltage. Ideal applications are amplifiers requiring a negative power supply. For a more-detailed example, see *Create an Inverting Power Supply From a Step-Down Regulator*, application report SLVA317.

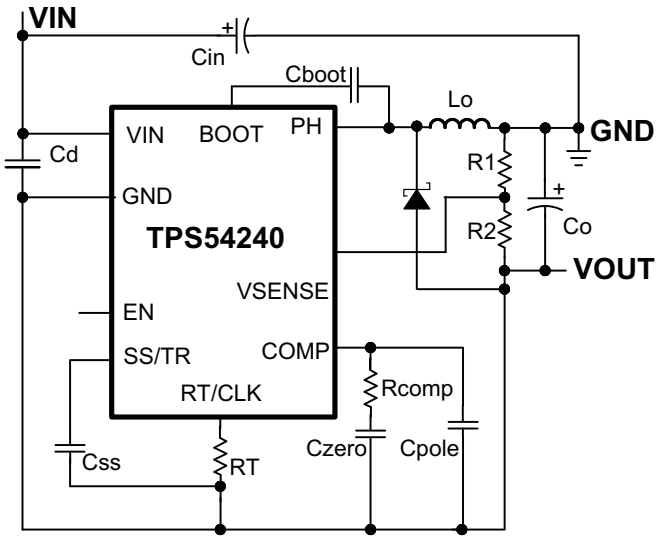


Figure 62. TPS54240 Inverting Power Supply

8.2.3 TPS54240 Split Rail Power Supply

This application circuit shows how to use the TPS54240 to convert a positive-input voltage to a split-rail positive- and negative-output voltage by using a coupled inductor. Ideal applications are amplifiers requiring a split-rail positive- and negative-voltage power supply. For a more-detailed example, see *Creating a Split-Rail Power Supply With a Wide Input Voltage Buck Regulator,* application report SLVA369.

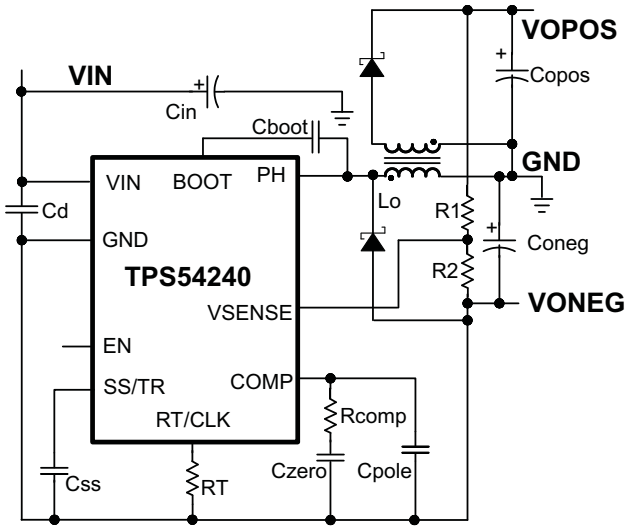


Figure 63. TPS54240 Split Rail Power Supply

8.2.4 12-V To 3.8-V GSM Power Supply

This application circuit is designed with TPS54240 device to power GSM-GPRS modules. GSM-GPRS modules typically require a power supply that can support large output current transients. For a more-detailed example, see *Creating GSM-GPRS Power Supply,* application report SLVA412.

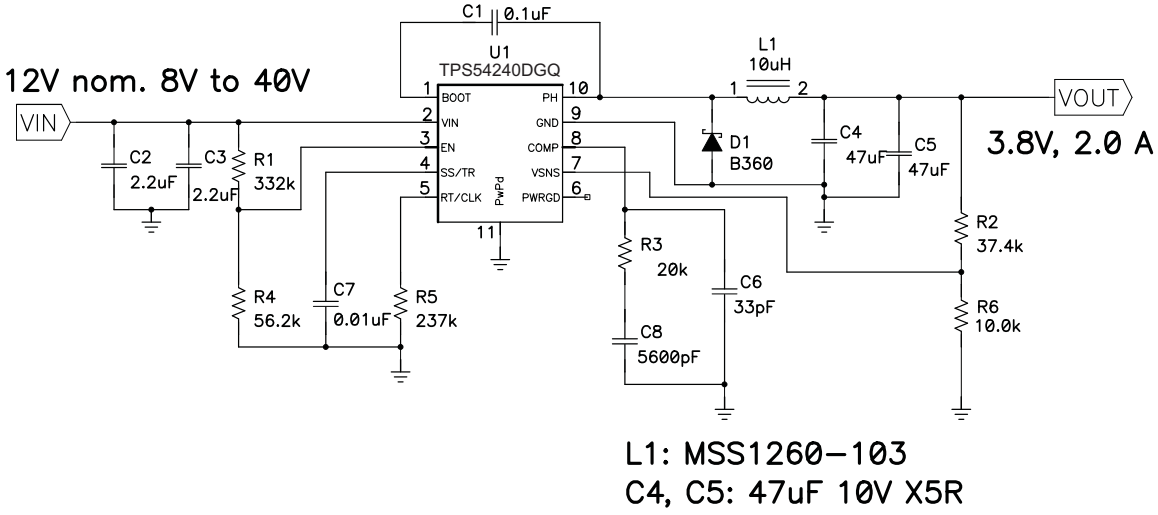


Figure 64. 12-V to 3.8-V GSM Power Supply

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8.2.5 24-V to 4.2-V GSM Power Supply

This application circuit is also designed to power GSM-GPRS modules. For a more-detailed example, see *Creating GSM-GPRS Power Supply,* application report SLVA412.

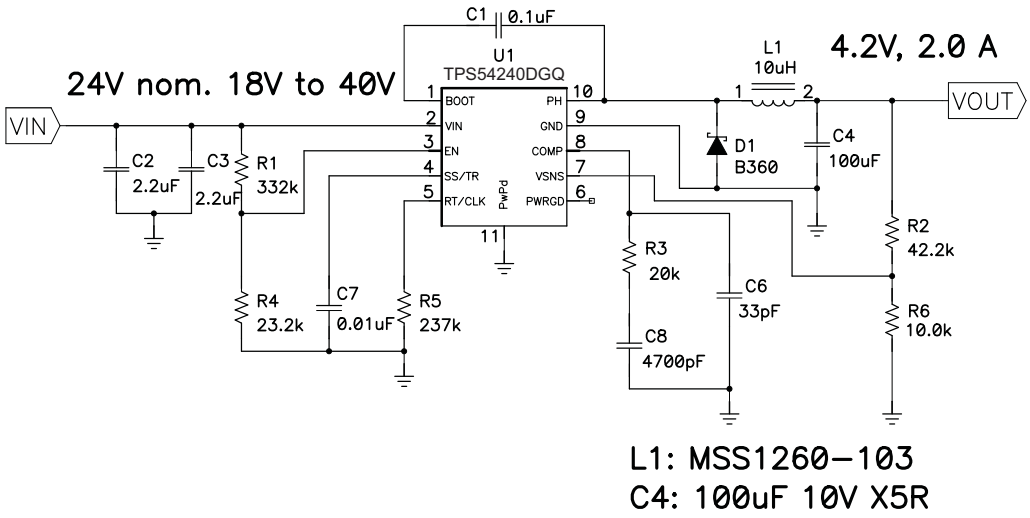


Figure 65. 24-V to 4.2-V GSM Power Supply

9 Power Supply Recommendations

The design of the device is for operation from an input voltage supply range between 3.5 V and 42 V. Good regulation of this input supply is essential. If the input supply is more distant than a few inches from the TPS54240 converter, the circuit may require additional bulk capacitance in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 100 µF is a typical choice.

10 Layout

10.1 Layout Guidelines

Layout is a critical portion of good power supply design. There are several signal paths that conduct fast changing currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise or degrade the power supplies performance. To help eliminate these problems, the VIN pin should be bypassed to ground with a low-ESR ceramic bypass capacitor with X5R or X7R dielectric. Take care to minimize the loop area formed by the bypass capacitor connections, the VIN pin, and the anode of the catch diode. See Figure 66 for a PCB layout example. The GND pin should be tied directly to the power pad under the IC and the power pad.

The power pad should be connected to any internal PCB ground planes using multiple vias directly under the IC. The PH pin should be routed to the cathode of the catch diode and to the output inductor. Since the PH connection is the switching node, the catch diode and output inductor should be located close to the PH pins, and the area of the PCB conductor minimized to prevent excessive capacitive coupling. For operation at full rated load, the top-side ground area must provide adequate heat dissipating area. The RT/CLK pin is sensitive to noise so the RT resistor should be located as close as possible to the IC and routed with minimal lengths of trace. The additional external components can be placed approximately as shown. It may be possible to obtain acceptable performance with alternate PCB layouts, however this layout has been shown to produce good results and is meant as a guideline.

10.2 Layout Example

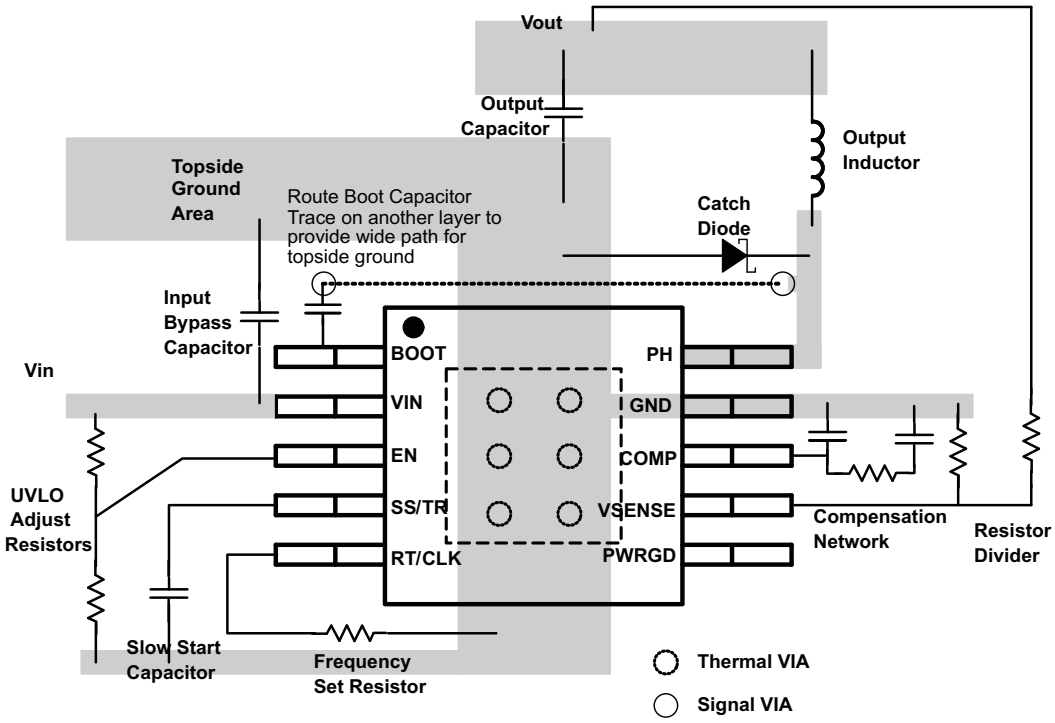


Figure 66. PCB Layout Example

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10.3 Estimated Circuit Area

The estimated printed circuit board area for the components used in the design of Figure 49 is 0.55 in^2. This area does not include test points or connectors.

11 Device and Documentation Support

11.1 Device Support

11.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

11.2 Documentation Support

11.2.1 Related Documentation

Create an Inverting Power Supply From a Step-Down Regulator, application report SLVA317

Creating a Split-Rail Power Supply With a Wide Input Voltage Buck Regulator, application report SLVA369

Creating GSM-GPRS Power Supply, application report SLVA412

11.3 Trademarks

Eco-Mode, PowerPAD are trademarks of Texas Instruments.
WEBENCH is a registered trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS54240DGQ	ACTIVE	HVSSOP	DGQ	10	80	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	54240	Samples
TPS54240DGQR	ACTIVE	HVSSOP	DGQ	10	2500	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	54240	Samples
TPS54240DRCR	ACTIVE	VSON	DRC	10	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	54240	Samples
TPS54240DRCT	ACTIVE	VSON	DRC	10	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	54240	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS54240 :

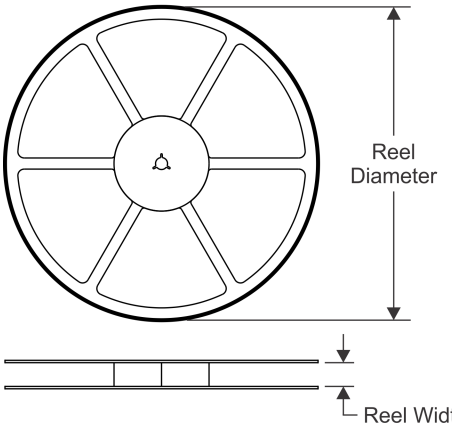
- Automotive: TPS54240-Q1

NOTE: Qualified Version Definitions:

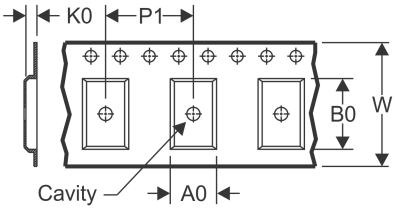
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

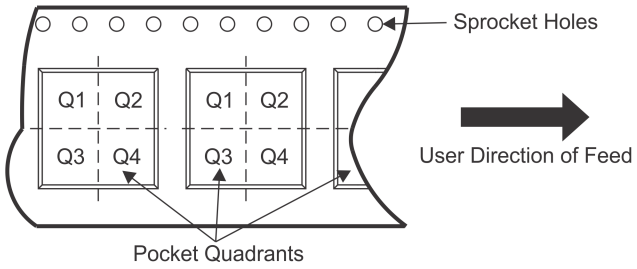


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

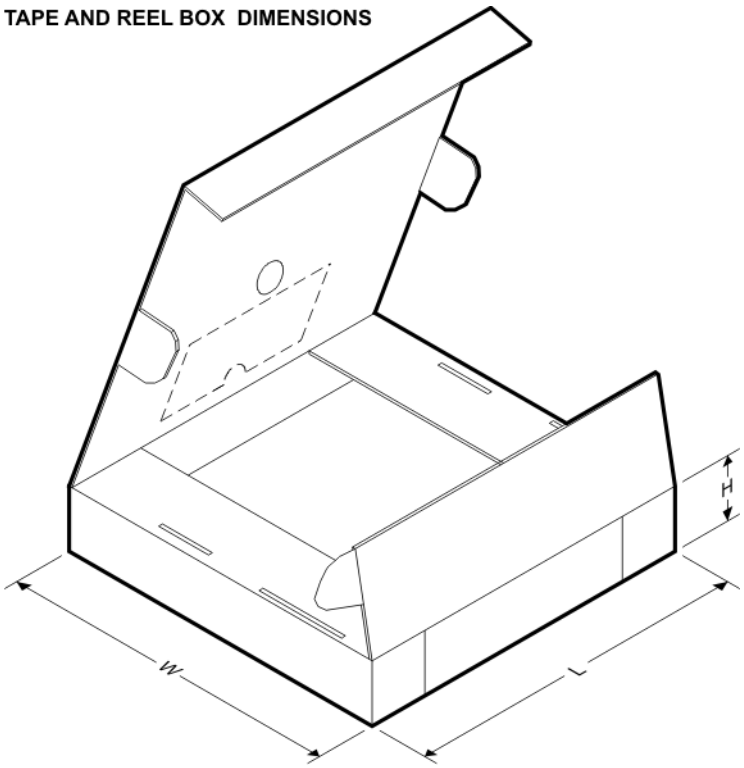
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS54240DGQR	HVSSOP	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS54240DGQR	HVSSOP	DGQ	10	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS54240DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS54240DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2

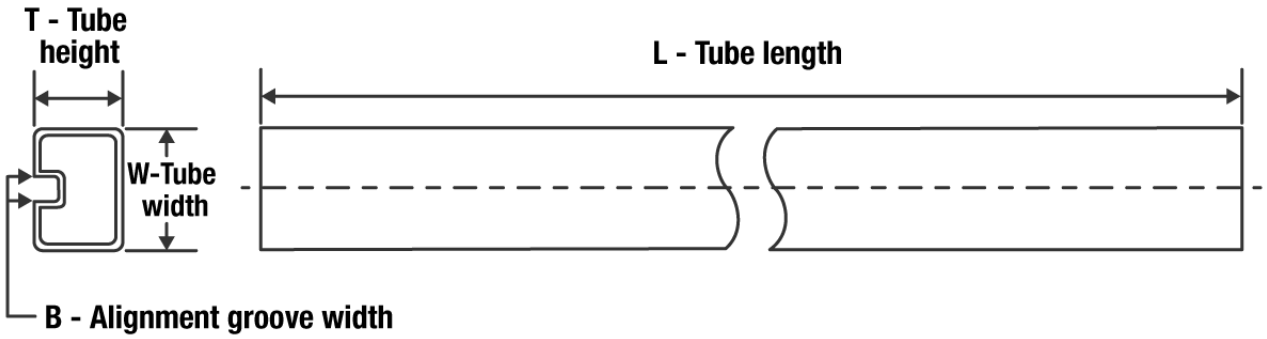
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS54240DGQR	HVSSOP	DGQ	10	2500	364.0	364.0	27.0
TPS54240DGQR	HVSSOP	DGQ	10	2500	346.0	346.0	35.0
TPS54240DRCR	VSON	DRC	10	3000	346.0	346.0	35.0
TPS54240DRCT	VSON	DRC	10	250	200.0	183.0	25.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TPS54240DGQ	DGQ	HVSSOP	10	80	330	6.55	500	2.88
TPS54240DGQ	DGQ	HVSSOP	10	80	322	6.55	1000	3.01

GENERIC PACKAGE VIEW

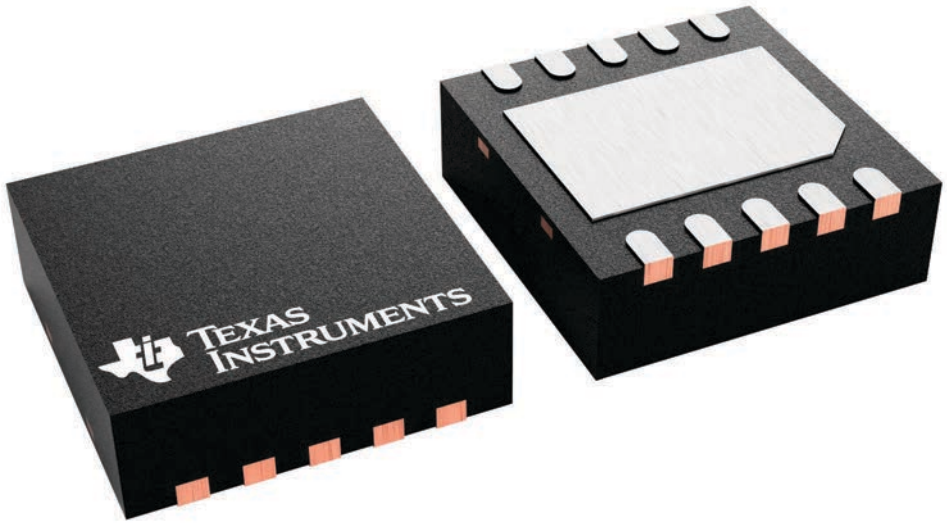
DRC 10

VSON - 1 mm max height

3 x 3, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



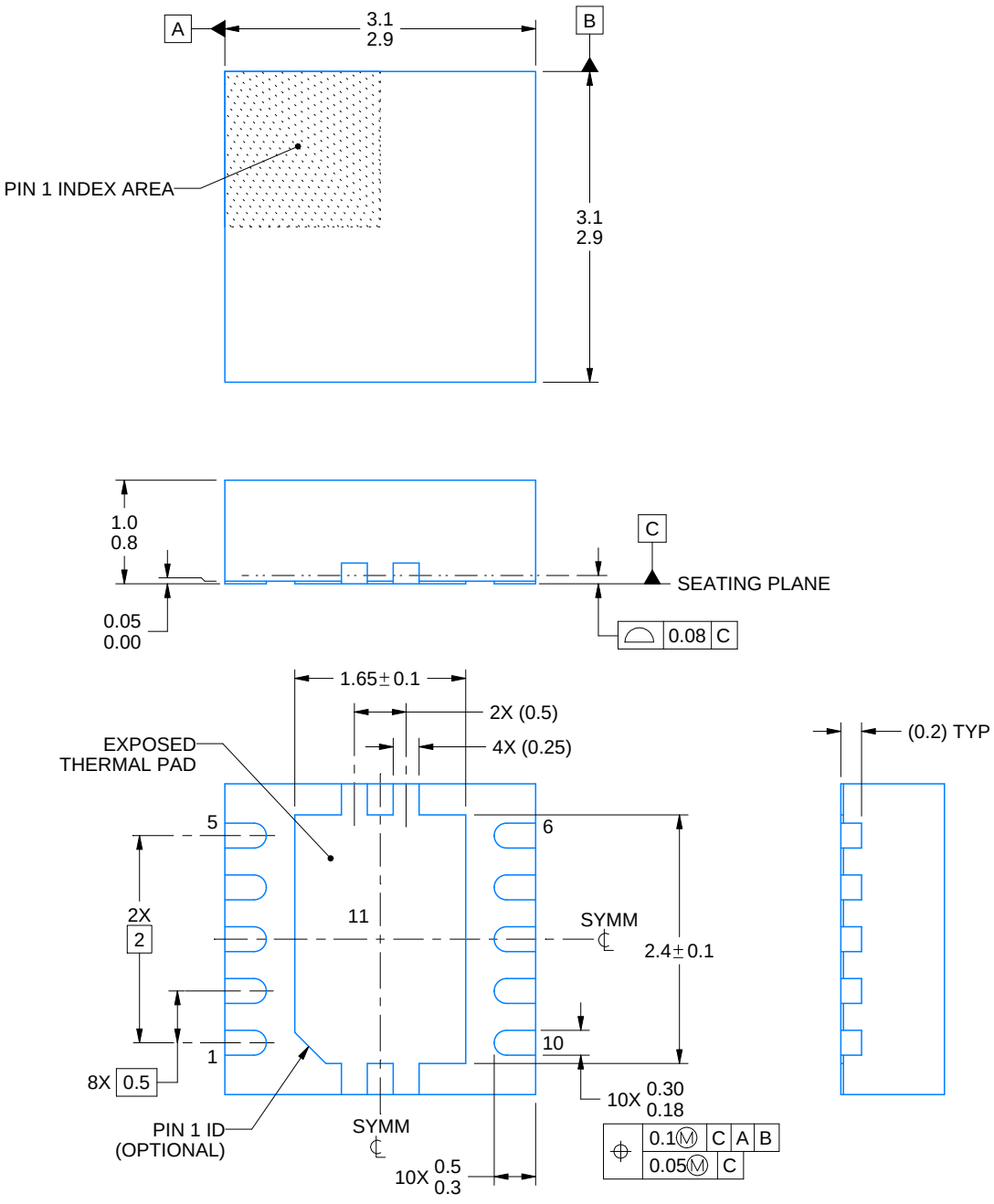
4226193/A

DRC0010J

PACKAGE OUTLINE

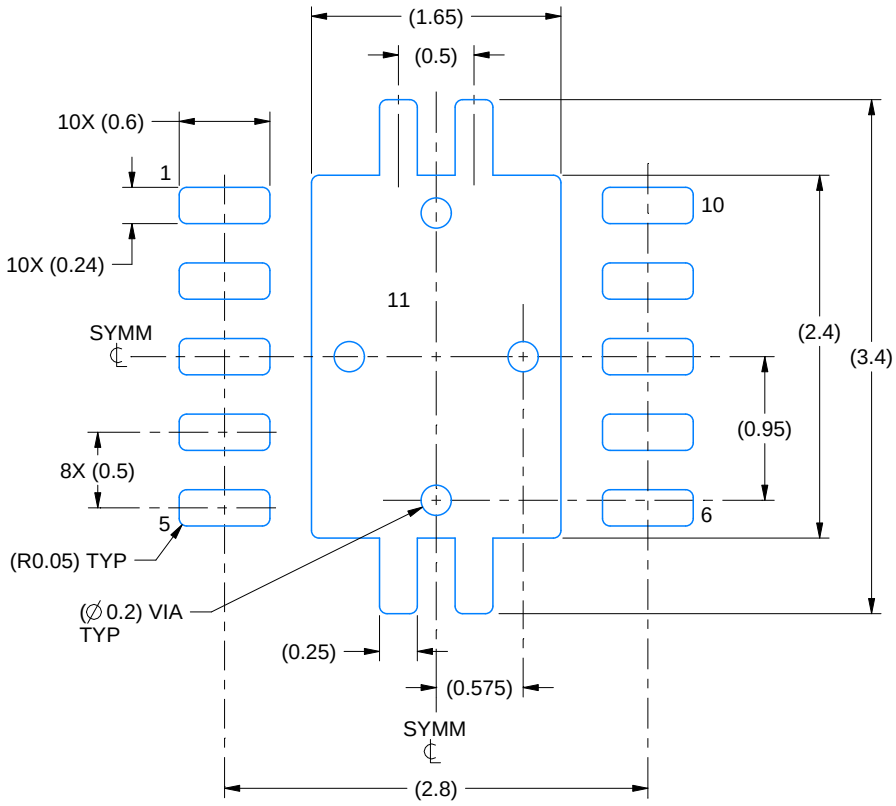
VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

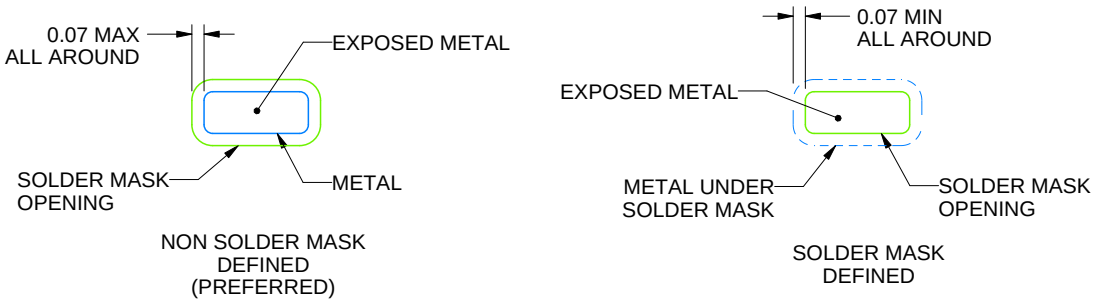


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

4218878/B 07/2018

NOTES: (continued)

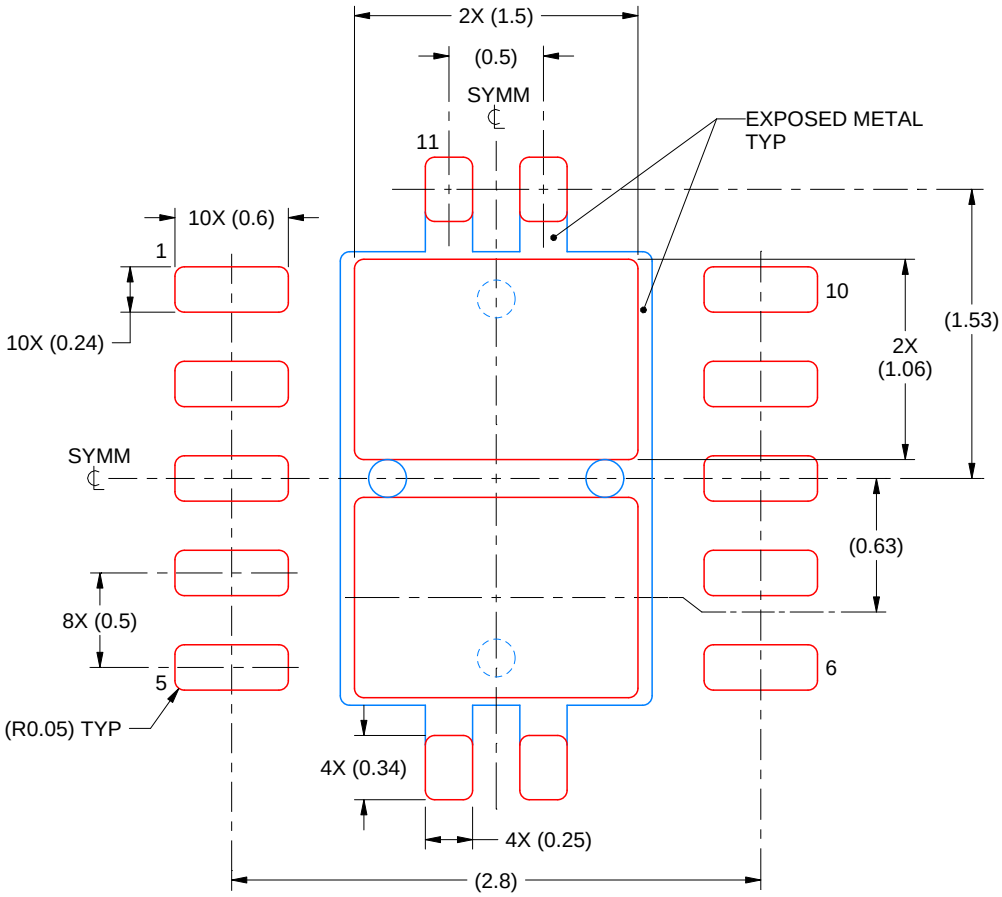
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DRC0010J

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 11:
80% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

4218878/B 07/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

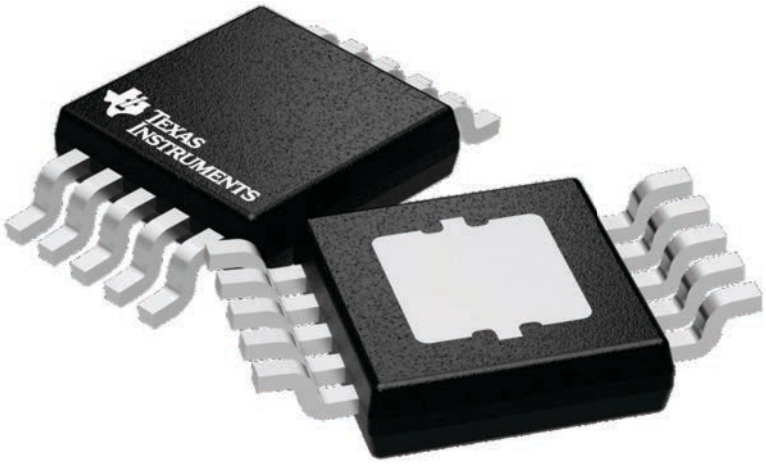
GENERIC PACKAGE VIEW

DGQ 10

PowerPAD™ HVSSOP - 1.1 mm max height

3 x 3, 0.5 mm pitch

PLASTIC SMALL OUTLINE



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

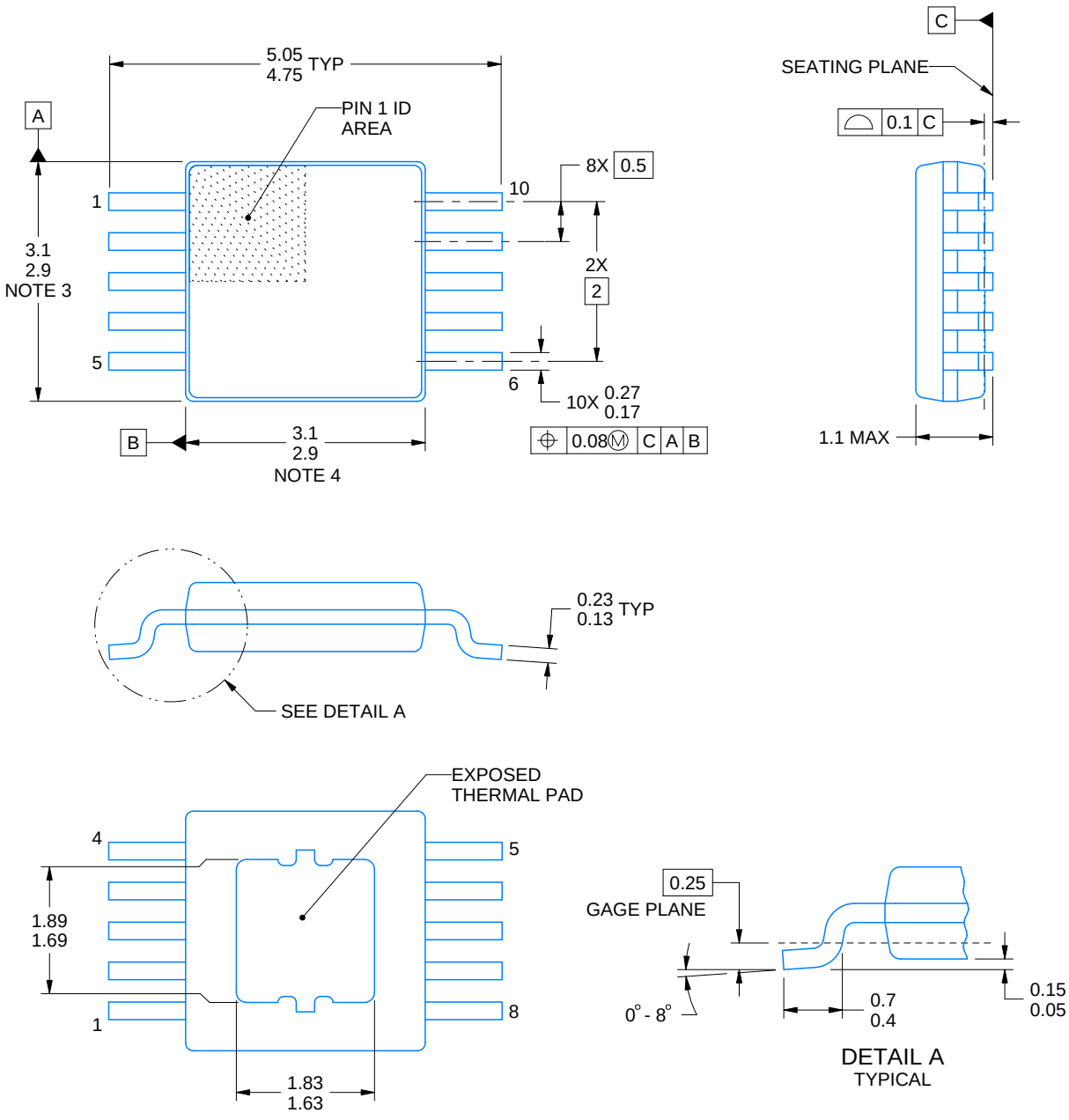
4224775/A

PACKAGE OUTLINE

DGQ0010D

PowerPAD™ - 1.1 mm max height

PLASTIC SMALL OUTLINE

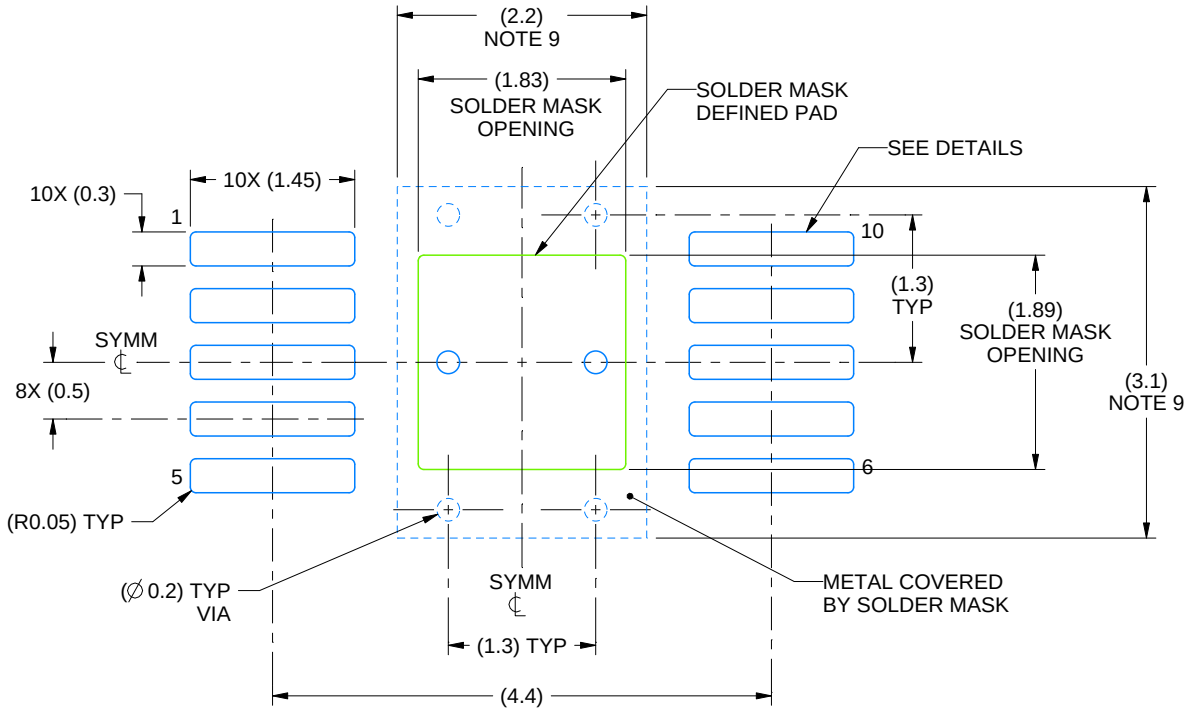


4218842/A 01/2019

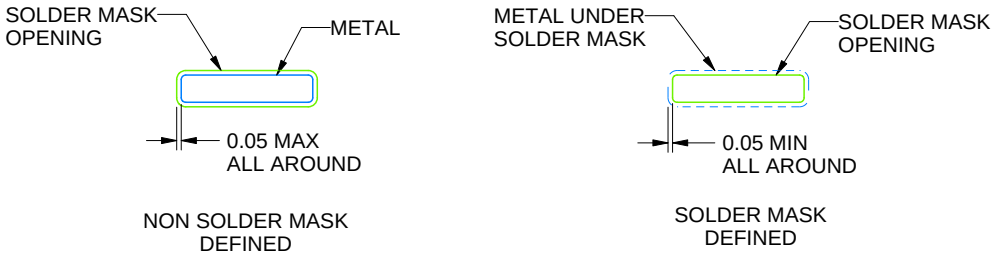
PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA-T.



LAND PATTERN EXAMPLE
SCALE:15X

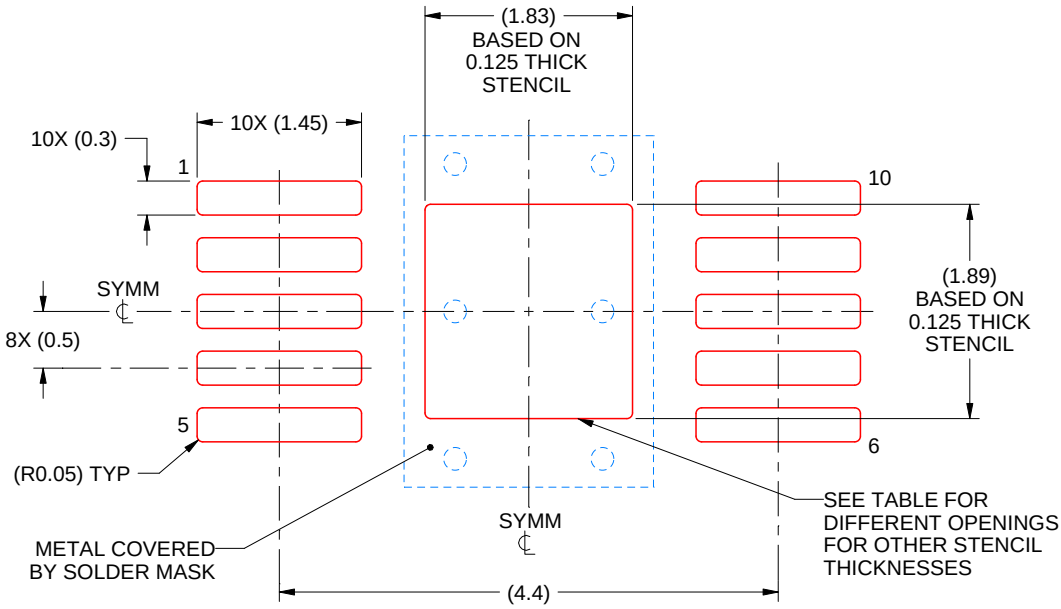


SOLDER MASK DETAILS

4218842/A 01/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	2.05 X 2.11
0.125	1.83 X 1.89 (SHOWN)
0.150	1.67 X 1.73
0.175	1.55 X 1.60

4218842/A 01/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

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